

Click [here](#) for production status of specific part numbers.

## MAX20343

# Ultra-Low Quiescent Current, Low Noise 3.5W Buck-Boost Regulator

### General Description

The MAX20343 is an ultra-low quiescent current, non-inverting buck-boost converter with 1A current capability at 3.5V intended for applications that require long run times while also demanding bursts of high current. The device employs a unique control algorithm which seamlessly transitions between buck, buck-boost, and boost modes, minimizing discontinuities and subharmonics in the output voltage ripple. The low 1.9V input voltage for startup allows users to power the device from a variety of sources, and the near-zero minimum operating voltage gives the user the ability to extract as much as possible from their energy source. The MAX20343 has also been designed to keep inductance and output capacitance requirements as low as possible for space-constrained applications.

The MAX20343 is ideal for power in optical sensor applications as well as for powering radios in low power, wide area network (LPWAN) applications since in both cases noise must be minimal and efficiency must be high. For instance, the small light-load output voltage ripple allows a photoplethysmography (PPG) system to operate at low LED currents without interference. Additionally, seamless transitions between operating modes enables the use of dynamic voltage scaling (DVS) to minimize headroom on the LED and to save power in such systems. In applications where a low-power-density battery must be buffered by a super-capacitor to provide large LPWAN type bursts of current, the ultra-low operating voltage of the MAX20343 allows the user to extract as much energy as possible from the super capacitor. The low output inductance/capacitance requirement allows a small total solution size. For example in PPG systems, this provides the flexibility to place the MAX20343 on a remote optical module if overcrowding on the main PCB is an issue.

The MAX20343 is available with a highly configurable I<sup>2</sup>C serial interface or as a single-pin-enabled fixed-programming version. See [Table 3](#) for specific device settings. The device operates over the -40°C to +85°C temperature range, is available in a 16-bump, 1.77mm x 2.01mm, 0.4mm pitch WLP package and a 12-pin, 2.50mm x 2.50mm, 0.5mm pitch FC2QFN package.

### Benefits and Features

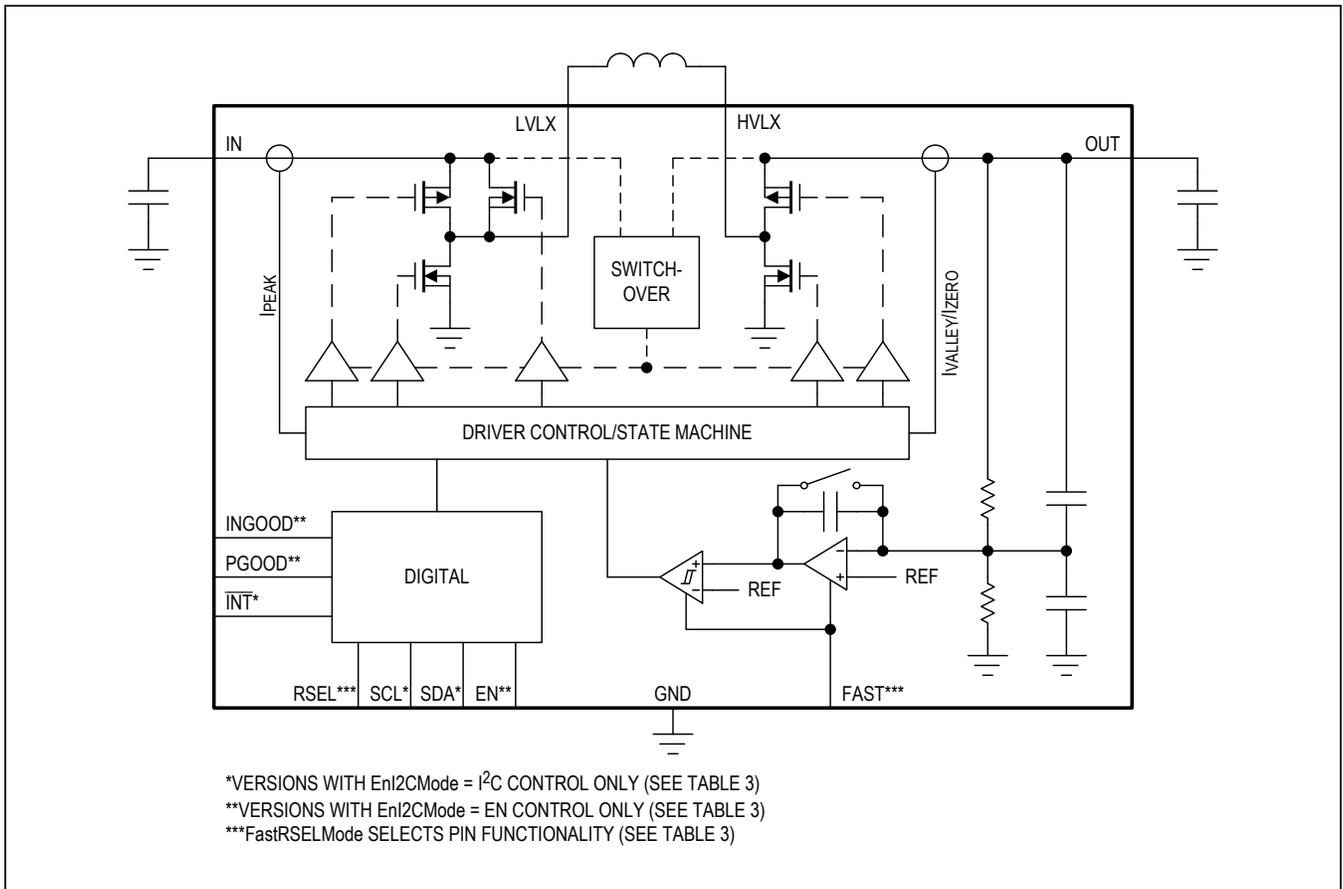
- Extend System Run Time
  - Ultra-Low, 3.5μA (typ) Quiescent Current
  - 250mW Output Power with 500mV Input Voltage
  - Dynamic Voltage Scaling (DVS)
- Low, Continuous Noise Profile
  - Eliminates Discontinuities Across Operating Voltage Range
  - Eliminates Post-Filtering LDO in Noise Sensitive Applications
- Adaptable Load Transient Response
  - Adjustable Peak Current for Optimal Performance in Each Application
  - Fast Load Transient Response Minimizes Settling Time
  - Optional Feedback Integrator
    - Enable for up to 3.5W Output Power Capabilities
    - Disable for up to 3.2W Output Power and Faster Load Transient Settling Time
  - FAST Pin Pretriggers Load Response and Offers Improved Load Transient
- Flexible Control Options
  - I<sup>2</sup>C Interface with Status Interrupts
  - EN and Status Pins, Single-Resistor V<sub>OUT</sub> Selection (RSEL)
  - See [Table 3](#) for specific device defaults
- Extended Operating Temperature from -40°C to +85°C
- Optimally Sized for Small Applications
  - 16-bump, 1.77mm x 2.01mm, 0.4mm Pitch WLP
  - 12-pin, 2.50mm x 2.50mm, Side-Wettable, 0.5mm Pitch Flip-Chip QFN
  - Inductor/Capacitor Available in 0603/0402 Case Sizes

### Applications

- Biometric Optical Sensing Including PPG
- LPWAN (LTE/NB-IoT, LTE/Cat-M1)
- IoT
- Industrial Sensors

[Ordering Information](#) appears at end of data sheet.

Simplified Block Diagram



**Absolute Maximum Ratings**

IN, OUT, SDA, SCL, EN, FAST, RSEL,  
PGOOD, INGOOD, INT, CAP .....-0.3V to +6.0V  
LVLX .....-0.3V to  $V_{IN} + 0.3V$   
HVLX .....-0.3V to  $\min(V_{OUT} + 0.3V, +6.0V)$   
Continuous Power Dissipation (Multilayer Board,  
 $T_A = +70^\circ C$ ) (4 x 4 Array 16-Ball, 1.77mm x 2.01mm, 0.4mm  
Pitch WLP) (derate 17.26mW/°C above +70°C) ....949.30mW

Continuous Power Dissipation (Multilayer Board,  
 $T_A = +70^\circ C$ ) (12-Pin, 2.50mm x 2.50mm, 0.5mm Pitch  
FC2QFN) (derate 17.04mW/°C above +70°C).....936.97mW  
Operating Temperature Range ..... -40°C to +85°C  
Junction Temperature ..... +150°C  
Storage Temperature Range ..... -40°C to +150°C  
Soldering Temperature (reflow) ..... +260°C

*Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.*

**Package Information**

<b>PACKAGE TYPE: 16-BUMP WLP</b>	
Package Code	W161C2+1
Outline Number	<a href="#">21-100328</a>
Land Pattern Number	Refer to <a href="#">Application Note 1891</a>
<b>THERMAL RESISTANCE, FOUR-LAYER BOARD:</b>	
Junction to Ambient ( $\theta_{JA}$ )	57.93°C/W

<b>PACKAGE TYPE: 12-PIN FC2QFN</b>	
Package Code	F122B2F+1
Outline Number	<a href="#">21-100331</a>
Land Pattern Number	<a href="#">90-100130</a>
<b>THERMAL RESISTANCE, FOUR-LAYER BOARD:</b>	
Junction to Ambient ( $\theta_{JA}$ )	58.70°C/W
Junction to Case ( $\theta_{JC}$ )	23.10°C/W

For the latest package outline information and land patterns (footprints), go to [www.maximintegrated.com/packages](http://www.maximintegrated.com/packages). Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to [www.maximintegrated.com/thermal-tutorial](http://www.maximintegrated.com/thermal-tutorial).

## Electrical Characteristics

( $V_{IN} = +1.8V$  to  $+5.5V$ ,  $C_{IN} = 5\mu F$ ,  $C_{OUT} = 8\mu F$ ,  $T_J = -40^\circ C$  to  $+85^\circ C$ , unless otherwise noted. Typical values are at  $T_A = +25^\circ C$ ,  $V_{IN} = +3.7V$ ,  $L = 1\mu H$ , Limits are 100% tested at  $T_A = +25^\circ C$ .) (Note 1)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS	
<b>BUCK-BOOST</b>								
Input Voltage Range	$V_{IN\_START}$	Input voltage required for startup (Note 2)		1.9		5.5	V	
Quiescent Supply Current	$I_Q$	No load, $V_{OUT} = 5V$ , $V_{IN} = 3.7V$	$V_{CAP}$ forced to $V_{IN}$		3.51	5	$\mu A$	
	$I_{Q\_FAST}$		FAST = 1		35		$\mu A$	
Shutdown Supply Current	$I_{SHDN}$	I <sup>2</sup> C controlled			0.3		$\mu A$	
Maximum Output Operative Power (Note 3)	$P_{MAX}$	Integrator enabled, $V_{IN} > 2.7V$ , $V_{OUT} \geq 3.2V$	BBstFETScale = 0, L = 1 $\mu H$ , $C_{OUT} = 8\mu F$	3.5			W	
			BBstFETScale = 1, L = 2.2 $\mu H$ , $C_{OUT} = 4\mu F$	1.75				
		Integrator disabled, $V_{IN} > 3.2V$ (Note 4), $V_{OUT} \geq 3.2V$	BBstFETScale = 0, L = 1 $\mu H$ , $C_{OUT} = 8\mu F$ , MAX20343B/E	2.8				
			BBstFETScale = 0, L = 1 $\mu H$ , $C_{OUT} = 8\mu F$ , All Other Versions	3.2				
			BBstFETScale = 1, L = 2.2 $\mu H$ , $C_{OUT} = 4\mu F$ , MAX20343B/E	1.6				
			BBstFETScale = 1, L = 2.2 $\mu H$ , $C_{OUT} = 4\mu F$ , All Other Versions	1.75				
Output Voltage Set Range	$V_{OUT}$	50mV step resolution		2.5		5.5	V	
			$V_{IN} < 2.1V$ , CAP forced to $V_{OUT}$ (see Input Operating Voltage section), MAX20343B/E	3.3		5.5		
			$V_{IN} < 2.1V$ , CAP forced to $V_{OUT}$ (see Input Operating Voltage section), All other versions	3.2		5.5		
Average Output Voltage Accuracy	ACC_OUT	$I_{OUT} = 1mA$ , $C_{OUT\_EFF} = 8\mu F$		-2.4		+2.4	%	
Line Regulation Error	$V_{LINE\_REG}$			-1		+1	%/V	
Load Regulation Error	$V_{LOAD\_REG}$	Integrator enabled, $V_{IN} = 2.7V$ , $V_{OUT} = 3.3V$ , BBstFETScale = 0, $P_{OUT} = 3.5W$			-1		%	
		Integrator disabled, $V_{IN} = 3.7V$ , $V_{OUT} = 5V$ , $P_{OUT} = 1.5W$ , BBstFETScale = 1, $C_{OUT} = 4\mu F$ , L = 2.2 $\mu H$			-3.2			
Line Transient Response	$V_{LINE\_TRAN}$	$V_{OUT} = 3.4V$ , $V_{IN}$ from 3.4V to 2.9V, 1 $\mu s$ fall time, $I_{LOAD} = 750mA$ , BBstIntegEn = 1, SwoFrcIN = 0			0		mV	
Load Transient Response	$V_{LOAD\_TRAN}$	$V_{OUT} = 5V$ , $V_{IN} = 3.7V$ , $I_{LOAD} = 10\mu A$ to 700mA, BBstIntegEn = 1			-150		mV	

## Electrical Characteristics (continued)

( $V_{IN} = +1.8V$  to  $+5.5V$ ,  $C_{IN} = 5\mu F$ ,  $C_{OUT} = 8\mu F$ ,  $T_J = -40^\circ C$  to  $+85^\circ C$ , unless otherwise noted. Typical values are at  $T_A = +25^\circ C$ ,  $V_{IN} = +3.7V$ ,  $L = 1\mu H$ , Limits are 100% tested at  $T_A = +25^\circ C$ .) (Note 1)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Input Supply Current During Startup	$I_{IN\_STUP}$	$V_{IN} = 3.6V$ , $V_{OUT} = 5V$ , $I_{LOAD} = 0$			1		$mA/C_{OUT}$ ( $\mu F$ )
Maximum Output Power During Startup (Note 3)	$I_{PWR\_MAX\_STUP}$	BBstFETScale = 0, MAX20343B/E		330	450		mW
		BBstFETScale = 0, All Other Versions		400	600		
		BBstFETScale = 1, MAX20343B/E		200	280		
		BBstFETScale = 1, All Other Versions		200	300		
Startup Time	$t_{STARTUP}$	Time from $V_{OUT} = 0V$ to final value	I <sup>2</sup> C controlled		9.6		ms
			RSEL, BBstRampEn = 0		32		
PGOOD Threshold	$V_{PGOOD}$				84.7		% $V_{OUT}$
PGOOD Threshold Hysteresis	$V_{PGOOD\_HYS}$				2.25		% $V_{OUT}$
Active Discharge Current	$I_{ACTD}$				20		mA
Passive Discharge Resistance	$R_{PSVD}$				1.2		k $\Omega$
Input UVLO Rising Threshold	$V_{IN\_UVLO\_R}$	$V_{IN}$ rising	Soft-start active, CAP forced to $V_{IN}$ , or $V_{OUT}$ set below 3.3V		1.836		V
			$V_{OUT}$ set higher than 3.3V, soft-start period complete		2.185		
Input UVLO Falling Threshold	$V_{IN\_UVLO\_F}$	$V_{IN}$ falling	Soft-start active, CAP forced to $V_{IN}$ , or $V_{OUT}$ set below 3.3V		1.782		V
			$V_{OUT}$ set higher than 3.3V, soft-start period complete		2.101		
Output UVLO Falling Threshold	$V_{OUT\_UVLO\_F}$	$V_{OUT}$ falling			1.873		V
Output UVLO Rising Threshold	$V_{OUT\_UVLO\_R}$	$V_{OUT}$ rising			1.963		V
<b>DIGITAL</b>							
SDA, EN, SCL, $\overline{INT}$ , PGOOD, INGOOD FAST, RSEL Input Leakage Current	$I_{LK\_IO}$	$T_J = +25^\circ C$		-1		+1	$\mu A$
SDA, EN, SCL, FAST Input Logic High	$V_{IO\_IH}$			1.4			V
SDA, EN, SCL, FAST Input Logic Low	$V_{IO\_IL}$					0.4	V

**Electrical Characteristics (continued)**

( $V_{IN} = +1.8V$  to  $+5.5V$ ,  $C_{IN} = 5\mu F$ ,  $C_{OUT} = 8\mu F$ ,  $T_J = -40^\circ C$  to  $+85^\circ C$ , unless otherwise noted. Typical values are at  $T_A = +25^\circ C$ ,  $V_{IN} = +3.7V$ ,  $L = 1\mu H$ , Limits are 100% tested at  $T_A = +25^\circ C$ .) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
SDA, $\overline{INT}$ , PGOOD, INGOOD Output Logic Low	$V_{IO\_OL}$	$I_{OL} = 4mA$			0.4	V
SCL Clock Frequency	$f_{SCL}$	MAX20343B/E	400		680	kHz
		All Other Versions			680	
Bus Free Time Between STOP and START Condition	$t_{BUF}$		0.75			$\mu s$
START Condition (Repeated) Hold Time	$t_{HD\_STA}$	(Note 5)	0.35			$\mu s$
Low Period of SCL Clock	$t_{LOW}$		0.75		1.25	$\mu s$
High Period of SCL Clock	$t_{HIGH}$		0.35			$\mu s$
Setup Time for a Repeated START Condition	$t_{SU\_STA}$		0.35			$\mu s$
Data Hold Time	$t_{HD\_DAT}$	(Note 6)	0		0.53	$\mu s$
Data Setup Time	$t_{SU\_DAT}$		100			ns
Setup Time for STOP Condition	$t_{SU\_STO}$		0.35			$\mu s$
Spike Pulse Widths Suppressed by Input Filter	$t_{SP}$		50			ns

**Note 1:** All devices are 100% production tested at  $T_A = +25^\circ C$ . Limits over the operating temperature range are guaranteed by design.

**Note 2:** Output power across the input operating voltage range is limited by input current. Refer to TOC03 for details on how the power limit changes with  $V_{IN}$ .

**Note 3:** The parameter is not production tested and values are generated through characterization only.

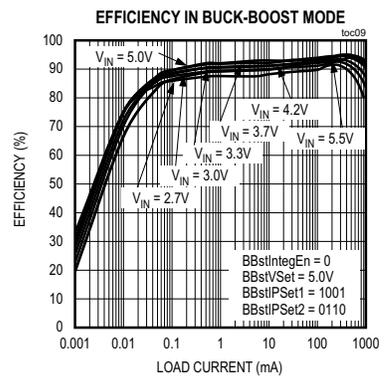
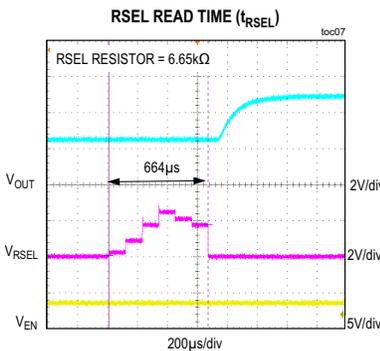
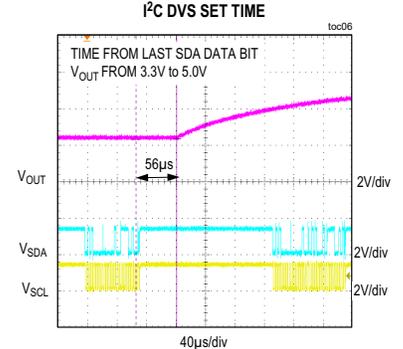
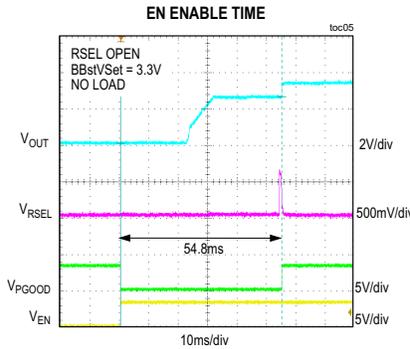
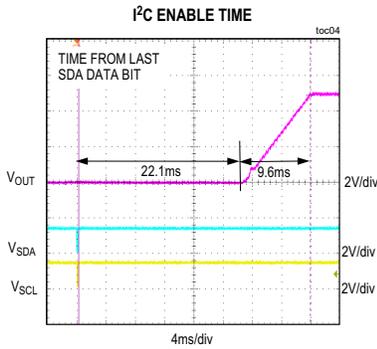
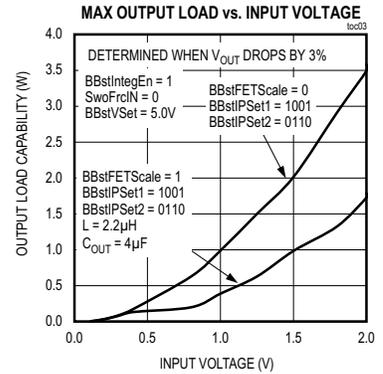
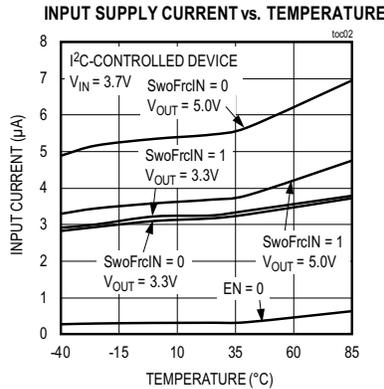
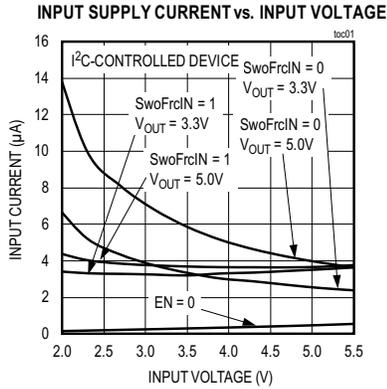
**Note 4:** Operation down to 2.7V is supported with the integrator disabled, but stability is only guaranteed up to 1.75W output power. Beyond 1.75W, oscillations could occur unless output capacitance is increased.

**Note 5:**  $f_{SCL}$  must meet the minimum clock low time plus the rise/fall times.

**Note 6:** The maximum  $t_{HD\_DAT}$  has to be met only if the device does not stretch the low period ( $t_{LOW}$ ) of the SCL signal.

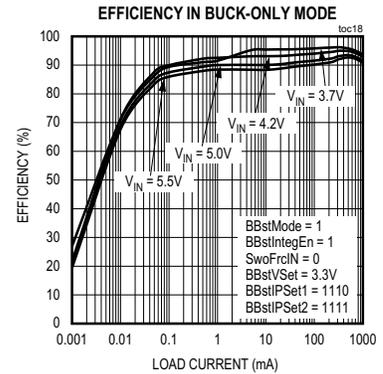
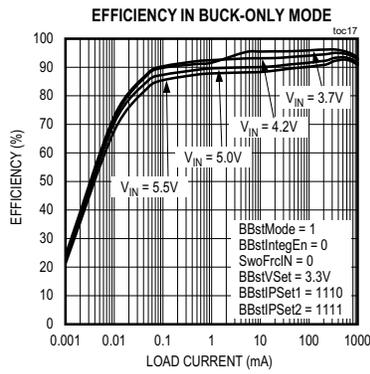
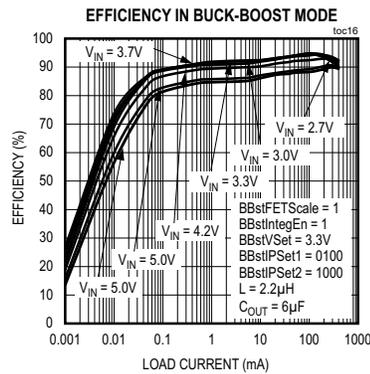
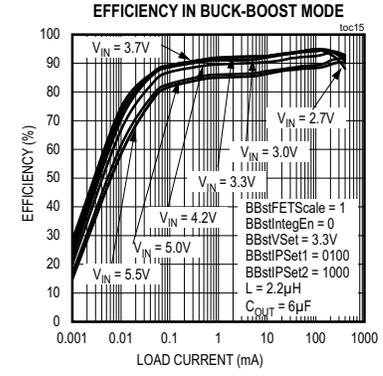
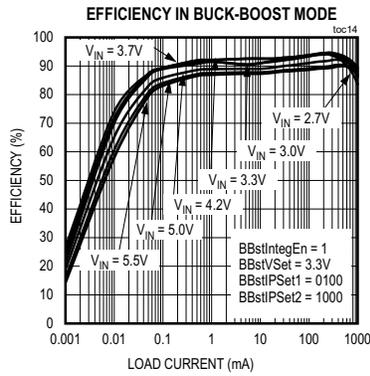
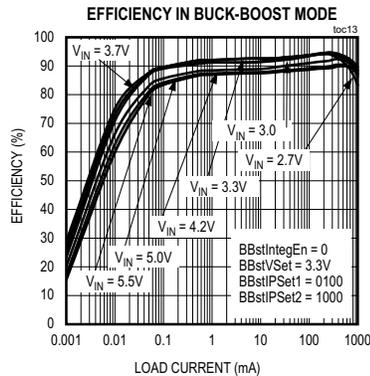
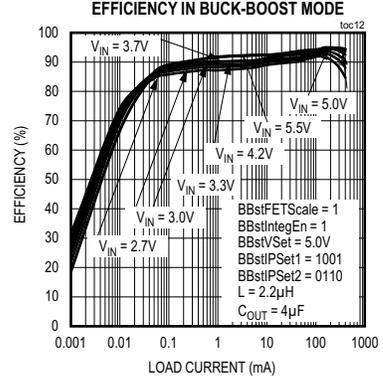
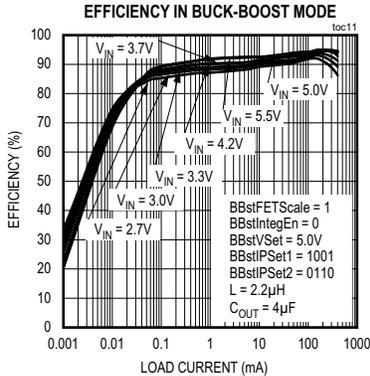
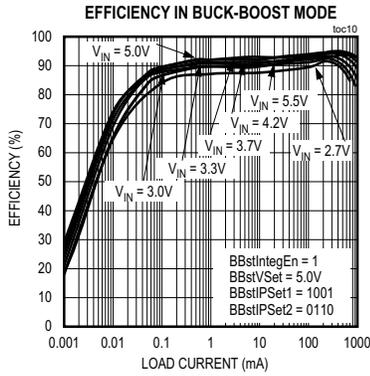
Typical Operating Characteristics

( $V_{IN} = +3.7V$ ,  $C_{IN} = GRM155R60J226ME11$ , refer to [Figure 9](#) single capacitor derating,  $C_{OUT} = 2x GRM155R60J226ME11$ ,  $L = 1\mu H$ ,  $BBstZCCmpDis = 0$ ,  $BBstLowEMI = 0$ ,  $BBstMode = 0$ ,  $SwoFrcIN = 1$ ,  $BBstIPAdptDis = 0$ ,  $BBstFETScale = 0$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)



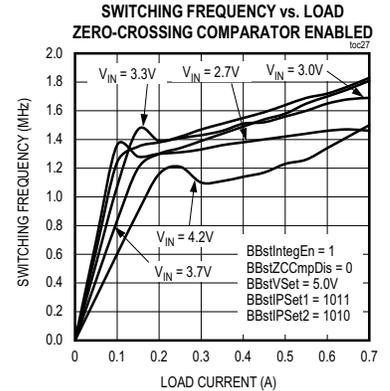
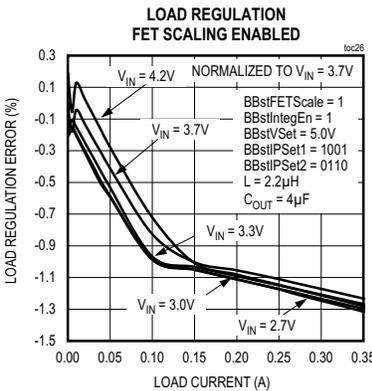
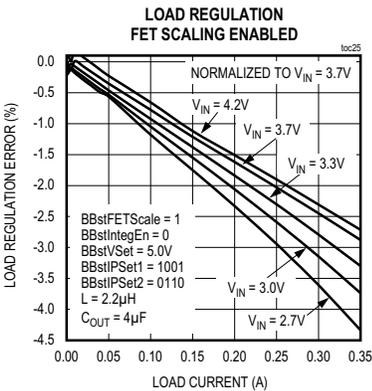
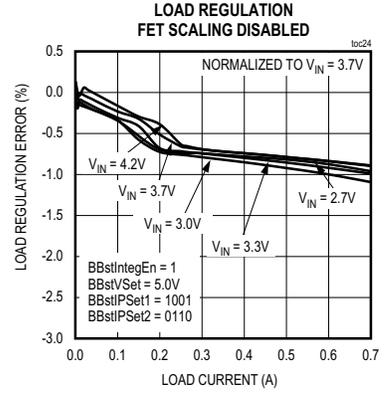
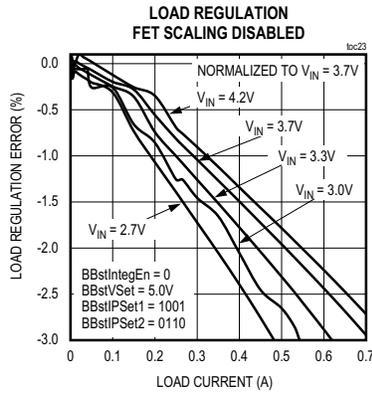
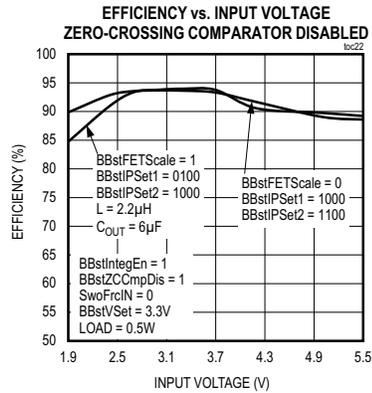
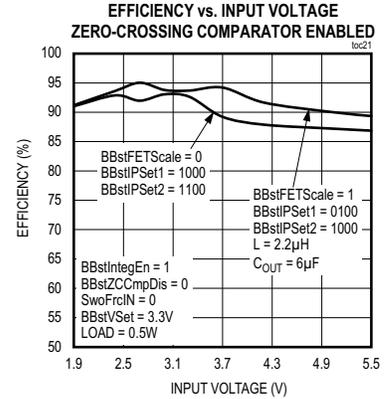
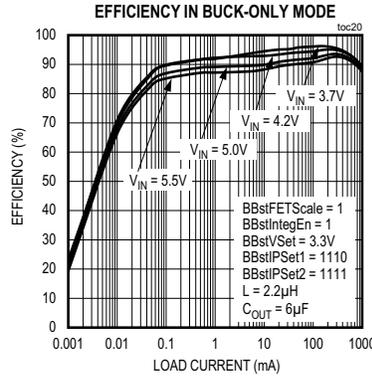
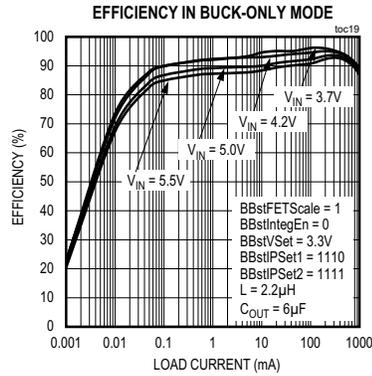
Typical Operating Characteristics (continued)

( $V_{IN} = +3.7V$ ,  $C_{IN} = GRM155R60J226ME11$ , refer to [Figure 9](#) single capacitor derating,  $C_{OUT} = 2x GRM155R60J226ME11$ ,  $L = 1\mu H$ ,  $BBstZCCmpDis = 0$ ,  $BBstLowEMI = 0$ ,  $BBstMode = 0$ ,  $SwoFrcIN = 1$ ,  $BBstIPAdptDis = 0$ ,  $BBstFETScale = 0$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)



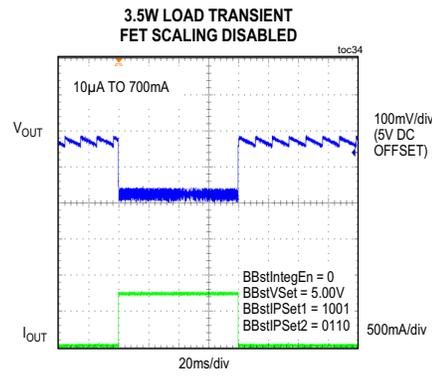
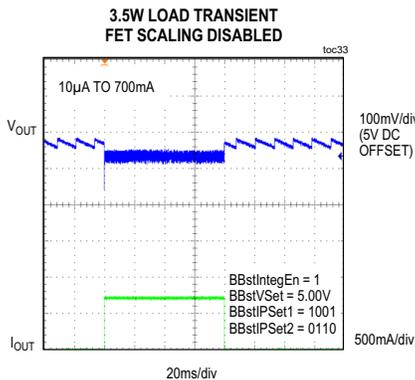
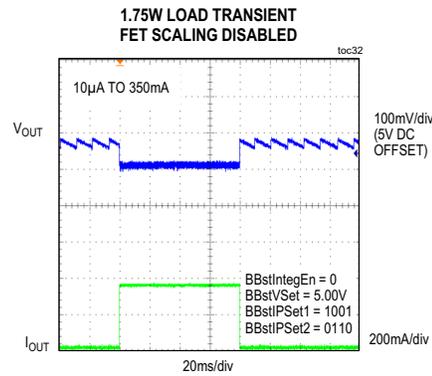
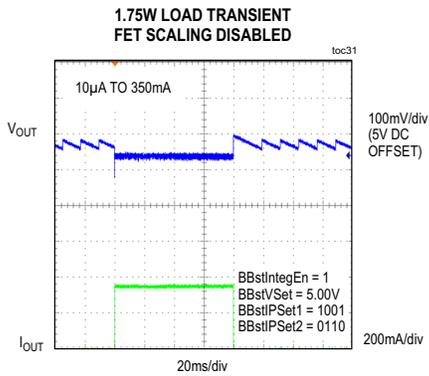
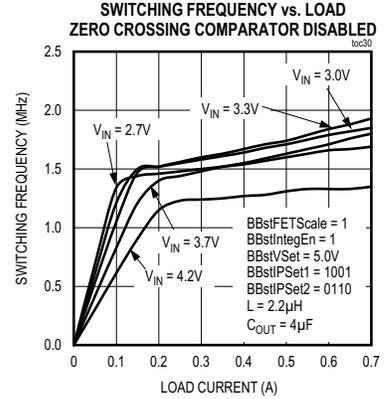
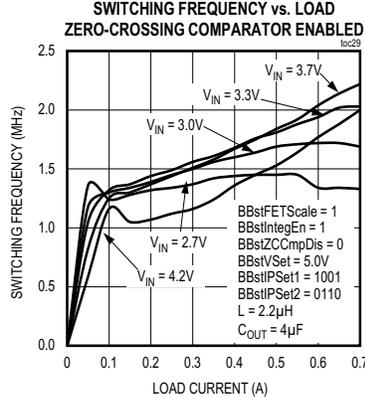
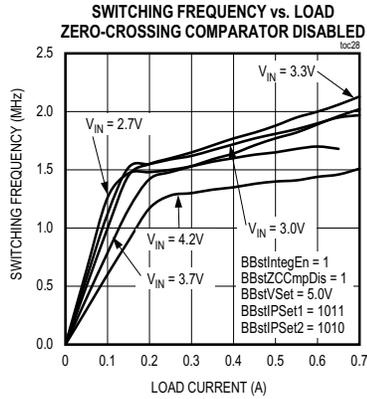
Typical Operating Characteristics (continued)

( $V_{IN} = +3.7V$ ,  $C_{IN} = GRM155R60J226ME11$ , refer to [Figure 9](#) single capacitor derating,  $C_{OUT} = 2x GRM155R60J226ME11$ ,  $L = 1\mu H$ ,  $BBstZCCmpDis = 0$ ,  $BBstLowEMI = 0$ ,  $BBstMode = 0$ ,  $SwofrcIN = 1$ ,  $BBstIPadptDis = 0$ ,  $BBstFETScale = 0$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)



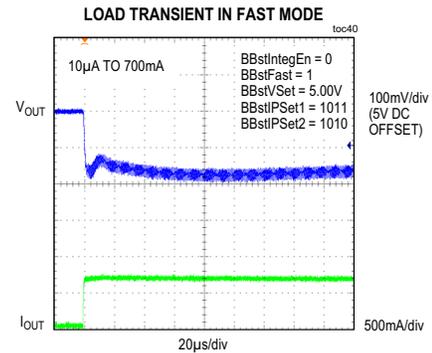
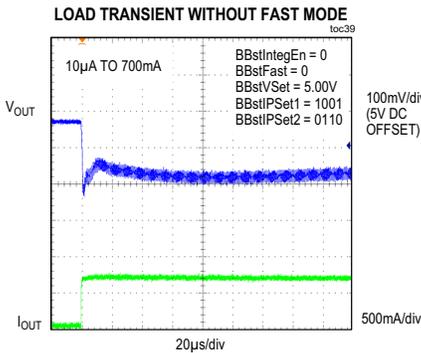
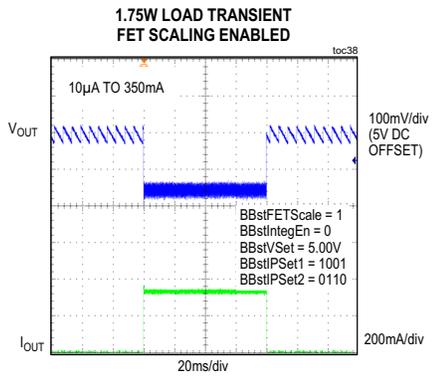
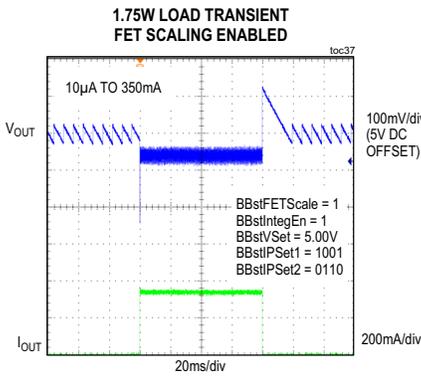
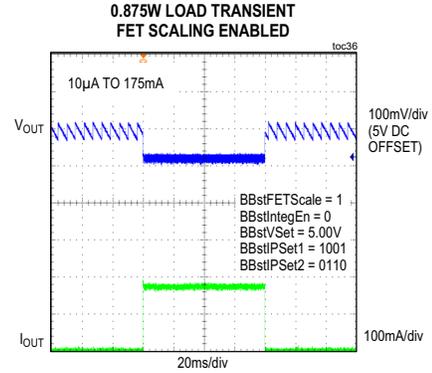
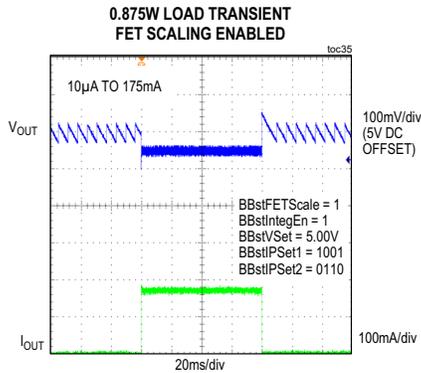
Typical Operating Characteristics (continued)

( $V_{IN} = +3.7V$ ,  $C_{IN} = GRM155R60J226ME11$ , refer to [Figure 9](#) single capacitor derating,  $C_{OUT} = 2x GRM155R60J226ME11$ ,  $L = 1\mu H$ ,  $BBstZCCmpDis = 0$ ,  $BBstLowEMI = 0$ ,  $BBstMode = 0$ ,  $SwoFrcIN = 1$ ,  $BBstIPAdptDis = 0$ ,  $BBstFETScale = 0$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)



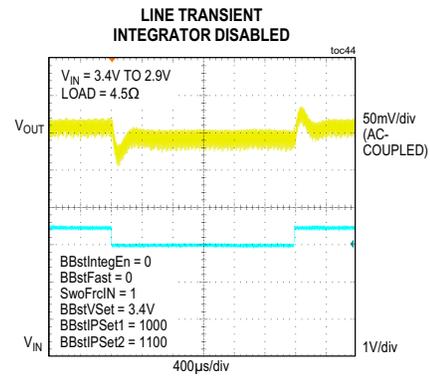
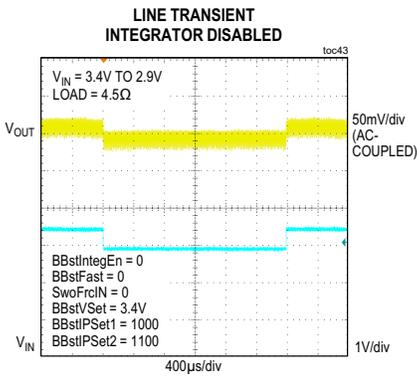
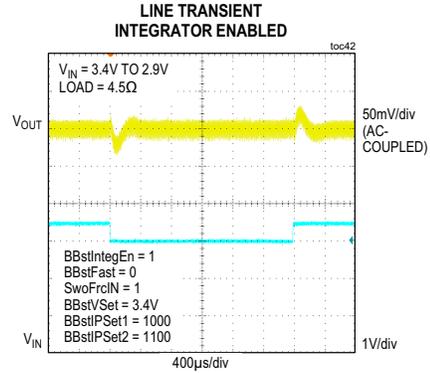
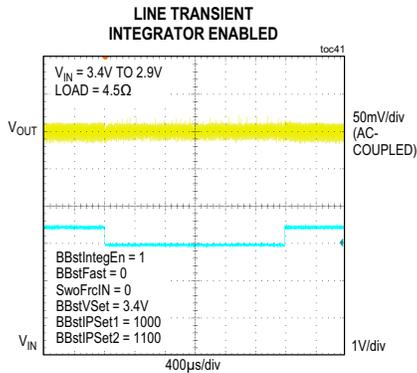
**Typical Operating Characteristics (continued)**

( $V_{IN} = +3.7V$ ,  $C_{IN} = GRM155R60J226ME11$ , refer to [Figure 9](#) single capacitor derating,  $C_{OUT} = 2 \times GRM155R60J226ME11$ ,  $L = 1\mu H$ ,  $BBstZCCmpDis = 0$ ,  $BBstLowEMI = 0$ ,  $BBstMode = 0$ ,  $SwoFrcIN = 1$ ,  $BBstIPAdptDis = 0$ ,  $BBstFETScale = 0$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)



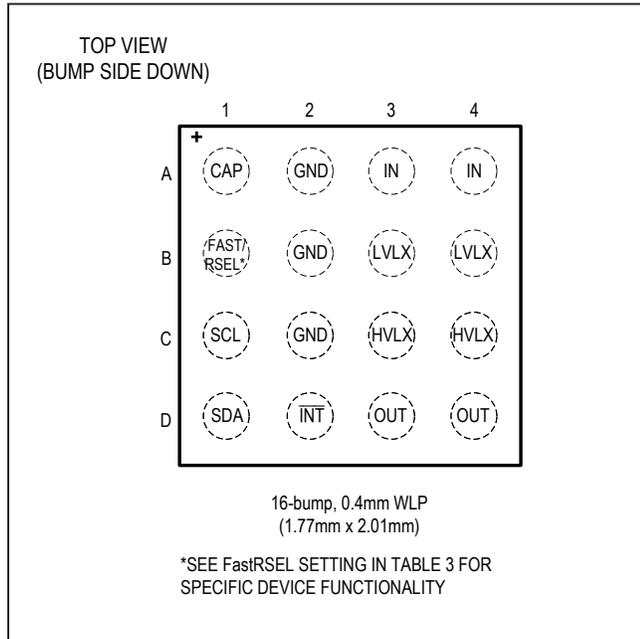
**Typical Operating Characteristics (continued)**

( $V_{IN} = +3.7V$ ,  $C_{IN} = GRM155R60J226ME11$ , refer to [Figure 9](#) single capacitor derating,  $C_{OUT} = 2 \times GRM155R60J226ME11$ ,  $L = 1\mu H$ ,  $BBstZCCmpDis = 0$ ,  $BBstLowEMI = 0$ ,  $BBstMode = 0$ ,  $SwoFrcIN = 1$ ,  $BBstIPAdptDis = 0$ ,  $BBstFETScale = 0$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)

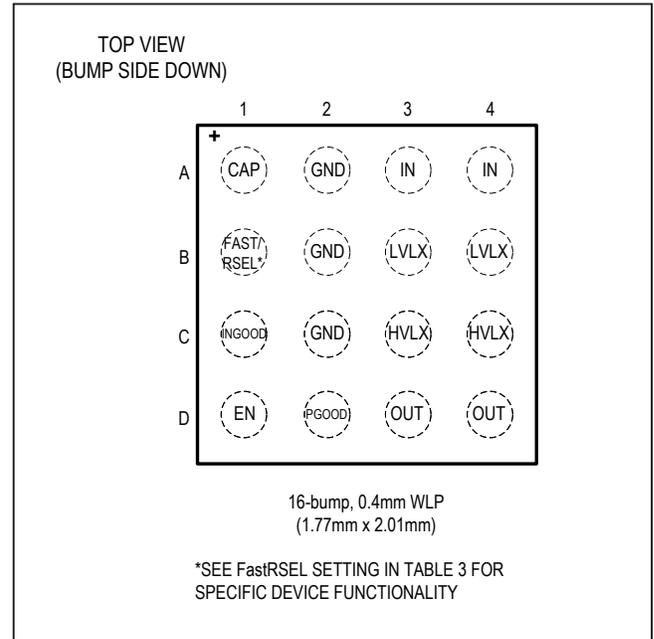


Pin Configuration

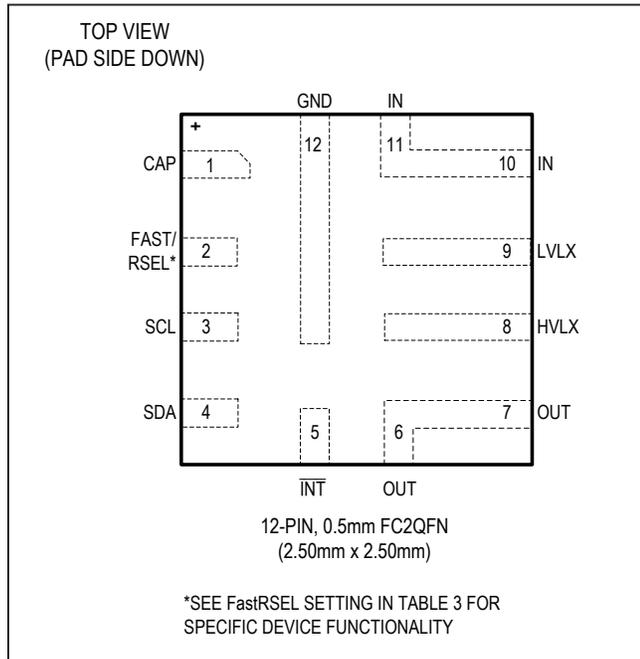
I<sup>2</sup>C-Controlled WLP



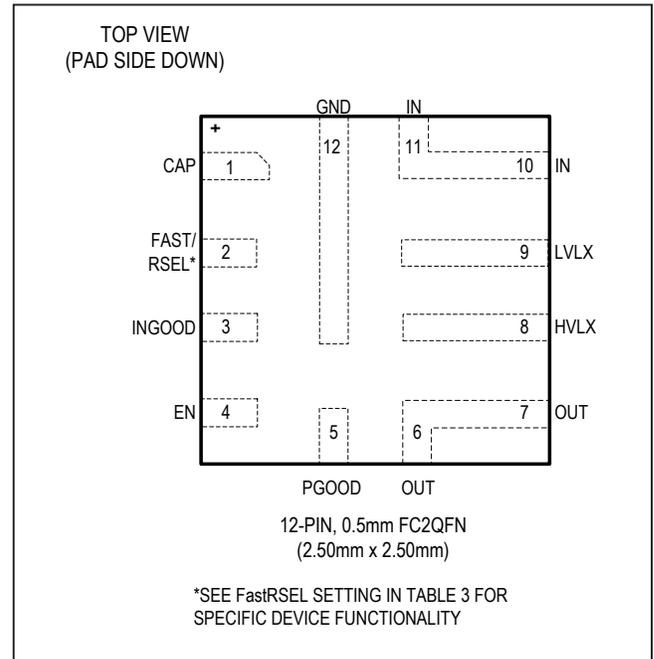
Single-Pin-Enabled WLP



I<sup>2</sup>C-Controlled FC2QFN



Single-Pin-Enabled FC2QFN



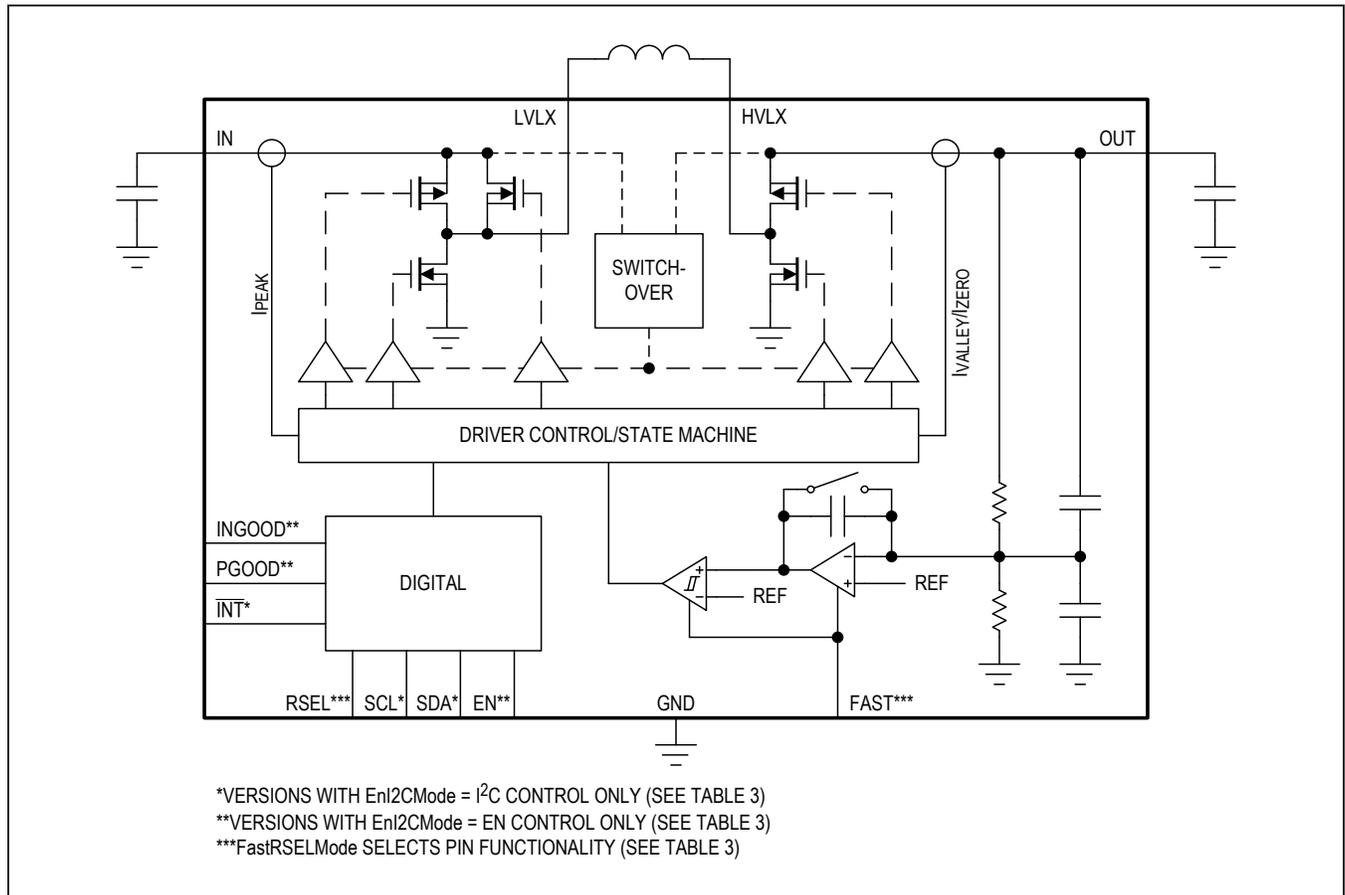
## Pin Description

PIN				NAME	FUNCTION
I <sup>2</sup> C- Controlled WLP	Single-Pin- Enabled WLP	I <sup>2</sup> C- Controlled FC2QFN	Single-Pin- Enabled FC2QFN		
A1	A1	1	1	CAP	Bypass Capacitor Connection for Internal Supply. Connect through 470nF of capacitance to GND.
A2, B2, C2	A2, B2, C2	12	12	GND	Ground
A3, A4	A3, A4	10, 11	10, 11	IN	Input Supply. Bypass to GND with effective capacitance equal to the minimum of 5 $\mu$ F and the value of the derating curve (Figure 9) for a bias voltage $V_{IN}$ placed as close to the device as possible.
B1	B1	2	2	FAST*	Fast Transient Response. When FAST is high, the quiescent current of MAX20343 increases in order to improve response time to a load step. When FAST is low, the quiescent current is decreased to save power.
B1	B1	2	2	RSEL*	Output Voltage Select. Connect a resistor from RSEL to GND based on the desired output voltage. See Figure 8.
B3, B4	B3, B4	9	9	LVLX	Switching Node. Connect to HVLX through a 1 $\mu$ H inductor if BBstFETScale = 0 or a 2.2 $\mu$ H inductor if BBstFETScale = 1.
C1	—	3	—	SCL	I <sup>2</sup> C Serial Clock Input. For I <sup>2</sup> C versions, note the BBstEn setting. If a version is disabled by default an externally supplied source must be used for the I <sup>2</sup> C interface to enable the output by I <sup>2</sup> C command.
—	C1	—	3	INGOOD	Input Power Good. LOW indicates that the CAP pin voltage is forced to $V_{OUT}$ and the input voltage is below $V_{IN\_UVLO\_F}$ when $V_{OUT} \geq 3.3V$ and the soft-start period is complete. Power capabilities might be limited. If CAP is forced to $V_{IN}$ , INGOOD does not function when $V_{IN} < V_{IN\_UVLO\_F}$ . It is an open drain output and should be connected to an external logic supply using a pullup resistor.
C3, C4	C3, C4	8	8	HVLX	Switching Node. Connect to LVLX through a 1 $\mu$ H inductor if BBstFETScale = 0 or a 2.2 $\mu$ H inductor if BBstFETScale = 1.
D1	—	4	—	SDA	I <sup>2</sup> C Serial Data Input/Open-Drain Output. For I <sup>2</sup> C versions, note the BBstEn setting. If a version is disabled by default an externally supplied source must be used for the I <sup>2</sup> C interface to enable the output by I <sup>2</sup> C command.
—	D1	—	4	EN	Enable. Active high.
D2	—	5	—	$\overline{INT}$	Interrupt Output. Open-drain, connect through pullup resistor to system logic supply.

\*The function of B1 is determined by the factory configuration of the device. See FastRSEL in Table 3 for the specific configuration of each device.

PIN				NAME	FUNCTION
I <sup>2</sup> C- Controlled WLP	Single-Pin- Enabled WLP	I <sup>2</sup> C- Controlled FC2QFN	Single-Pin- Enabled FC2QFN		
—	D2	—	5	PGOOD	Power Good Output. Indicates when output is ready for use. It is an open drain output and should be connected to an external logic supply using a pullup resistor.
D3, D4	D3, D4	6, 7	6, 7	OUT	Buck-Boost Output. If BBstFETScale = 0, bypass to GND with effective capacitance equal to twice the value of the derating curve (Figure 9) for a bias voltage V <sub>OUT</sub> , placed as close to the device as possible. If BBstFETScale = 1, bypass to GND with effective capacitance equal to the value of the derating curve (Figure 9) for a bias voltage V <sub>OUT</sub> , placed as close to the device as possible.

Functional Diagram



### Detailed Description

The MAX20343 is an ultra-low quiescent current, non-inverting buck-boost converter with 1A current capability at 3.5V intended for applications that require long run times while also demanding bursts of high current. A peak/valley current-controlled hysteretic architecture yields a fast transient response time with minimal settling time that allows the device to handle large load transients in high peak-power applications. The device has a unique control algorithm that seamlessly transitions between buck, buck-boost, and boost operation to minimize discontinuities and sub-harmonic noise in the output ripple.

The low, 1.9V startup voltage is compatible with a variety of power sources, and the near-zero minimum operating voltage extracts as much energy as possible from the source. Low inductance and capacitance requirements allow for a small total-solution size and make the MAX20343 well-suited for space-constrained applications. The device has a high efficiency and low noise that also makes it suitable for wireless and noise-sensitive applications such as LPWAN and optical sensor systems. It has an ultra-low, 3.5µA (typ) quiescent current and discontinuous conduction mode (DCM) to operate at low loads and extend run time in low average-power, battery-powered applications

### Startup Voltage

The MAX20343 is guaranteed to start up with a minimum input voltage of 1.9V. After device startup, an internal bootstrapping function allows the device to operate to very low input voltages limited only by the amount of current that can be drawn effectively from the input. See the [Input Operating Voltage](#) section for more details.

### Architectural Description

The MAX20343 buck-boost comprises a typical non-inverting buck-boost topology. [Figure 1](#) illustrates the

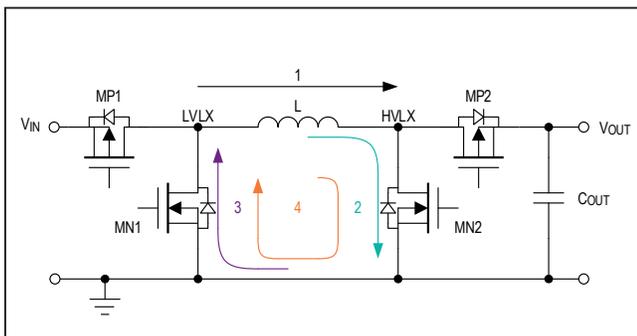


Figure 1. The Buck-Boost Regulator and Switching Phases

basic structure of the regulator with arrows depicting the inductor current flow in each switching phase.

### Switching Phases

Depending on the register settings and input-to-output voltage relationship, the buck-boost sequences through the below switching phases in a particular order to deliver charge to the output. Only two switches are on in each phase.

- Phase 1: MP1 on, MP2 on. Inductor charges.
- Phase 2: MP1 on, MN2 on. Inductor charges.
- Phase 3: MN1 on, MP2 on. Inductor discharges.
- Phase 4: MN1 on, MN2 on. Freewheeling.

### Buck-Boost Mode

When  $BBstMode = 0$  (register 0x01[2]), the regulator operates in buck-boost mode. The inductor charges in Phase 2 up to  $BBstIPSet1$  (register 0x03[3:0]). The buck-boost then transitions to Phase 1. If  $V_{IN} > V_{OUT}$ , the inductor continues charging until either the current reaches  $BBstIPSet1 + BBstIPSet2$  (register 0x03[7:4]) or after a 500ns delay. If  $V_{IN} \leq V_{OUT}$ , the buck-boost waits for the 500ns timeout to elapse or until the current drops to the valley limit. Next, the regulator enters Phase 3 to discharge the inductor current to the valley limit. When the inductor current reaches the valley-current crossing threshold or falls below 0, the regulator freewheels in Phase 4 until the next charge phase. When operating in continuous conduction mode (CCM), the buck-boost enters Phase 4 for approximately 30ns if  $BBstZCCmpDis = 1$  (register 0x01[4]). The buck-boost skips Phase 4 when operating in CCM and  $BBstZCCmpDis = 0$ . The valley behavior is determined by  $BBstZCCmpDis$ . [Figure 2](#) shows the inductor current in buck-boost mode.

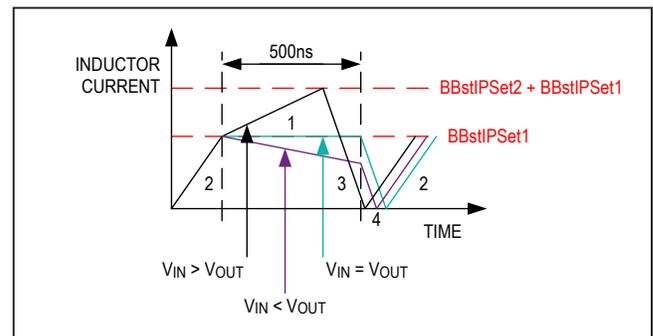


Figure 2. Buck-Boost Inductor Current in Buck-Boost Mode

**Buck-Only Mode**

To maximize efficiency when  $V_{IN} > V_{OUT}$ , the buck-boost regulator has a buck-only mode. When  $BBstMode = 1$ , the regulator behaves as a synchronously rectified buck regulator. If the device is set to buck-only mode, the regulator never enters Phase 2. Instead, the inductor is always charged in Phase 1. The inductor charges until its current reaches  $BBstIPSet1$  or the 500ns timeout elapses. The regulator then transitions to Phase 3 to provide a path to deliver the inductor current to the output. [Figure 3](#) shows the inductor current in buck-only mode.

Buck-only mode reduces switching losses present in buck-boost mode. Buck-only mode should be used when  $V_{OUT}$  is always less than  $V_{IN}$ .

**Inductor Peak and Valley Current Limits**

The buck-boost regulator monitors the maximum and minimum values of the inductor current. If  $BBstIPAdptDis = 1$  (register 0x04[1]), the peak currents are fixed to the values in  $BBstIPAdptDis$  (register 0x03) and the valley current is fixed to 0mA. If  $BBstAdptDis = 0$ , the peak and valley currents are allowed to change based on load requirements.

Peak currents are set in the  $BBstIPSet$  register.  $BBstIPSet1$  controls the peak current when  $V_{IN} < V_{OUT}$  and begins the timeout period for Phase 1.  $BBstIPSet2$  sets a secondary current limit in buck-boost mode when  $V_{IN} >$

$V_{OUT}$ . The total inductor current limit when  $V_{IN} > V_{OUT}$  is  $BBstIPSet1 + BBstIPSet2$ . The buck-boost regulator transitions from Phase 1 to Phase 3 if the inductor current reaches  $BBstIPSet1 + BBstIPSet2$  or if the 500ns timeout has elapsed. Minimizing the difference between  $BBstIPSet1$  and  $BBstIPSet2$  reduces the output ripple, but decreases efficiency. Care must be taken to optimize the peak current settings to keep a low output ripple while maximizing efficiency. [Figure 4](#) and [Figure 5](#) present the safe operating area of  $BBstIPSet2$  with respect to  $BBstIPSet1$ . Selecting values outside of the limits shown in [Figure 4](#) and [Figure 5](#) can cause unwanted behavior. [Figure 6](#) and [Figure 7](#) are graphical guides to selecting combinations of  $BBstIPSet1$  and  $BBstIPSet2$  to balance efficiency and voltage ripple for specific  $BBstVSet$  values.

In order to control inrush current during startup, the MAX20343 forces discontinuous conduction mode during startup (valley current is always 0) and overrides the peak current settings with  $BBstIP1SS$  and  $BBstIP2SS$ . Once the output reaches its final voltage, continuous conduction mode is allowed and the  $BBstIPSet1$  and  $BBstIPSet2$  settings are restored. See  $BBstIP1SS$  and  $BBstIP2SS$  ([Table 3](#)) for device-specific values.

The MAX20343 behavior when  $BBstIPAdptDis = 0$  can be further defined with a zero current comparator. The device transitions to Phase 4 when its control loop detects a zero current crossing.

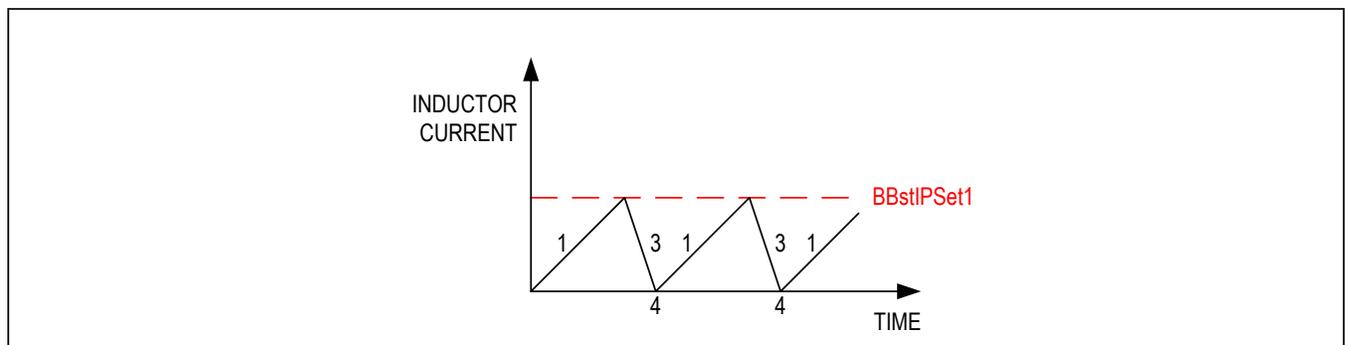


Figure 3. Buck-Boost Inductor Current in Buck-Only Mode

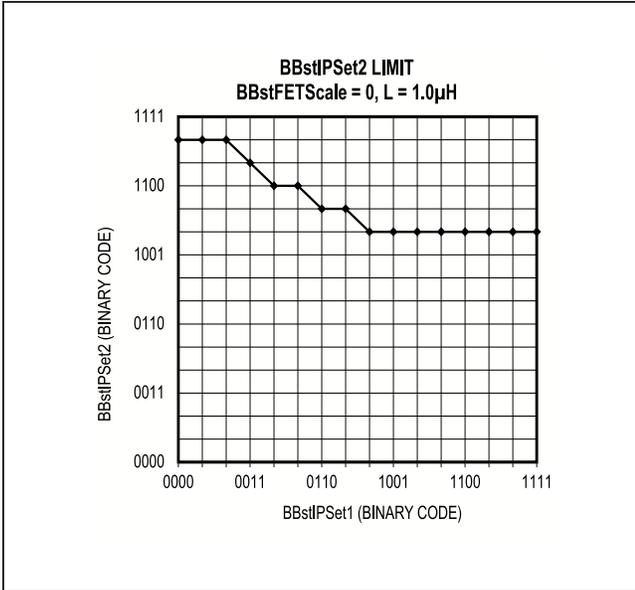


Figure 4. Minimum BBstIPSet2 Limit for a Given BBstIPSet1 Setting for BBstFETScale = 0 (MAX20343B/E Only)

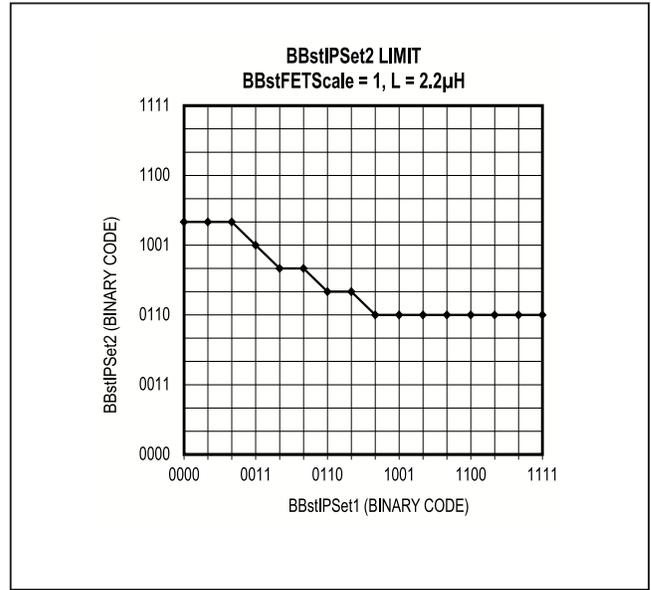


Figure 5. Minimum BBstIPSet2 Limit for a Given BBstIPSet1 Setting for BBstFETScale = 1 (on MAX20343B/E, and for either BBstFETScale setting for all other versions)

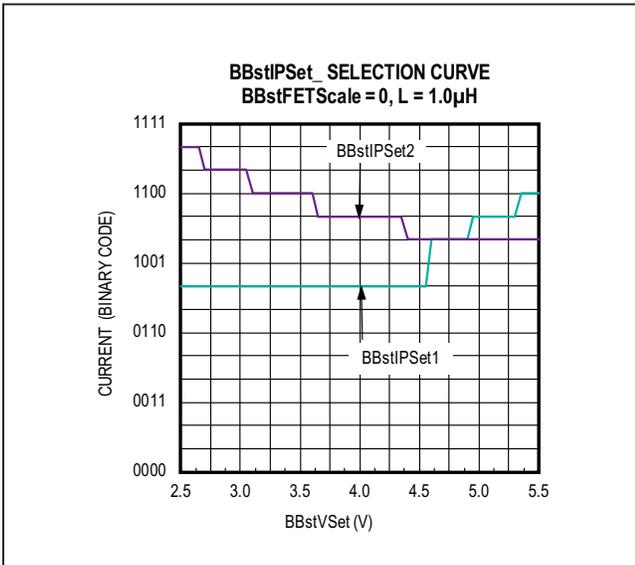


Figure 6. Recommended BBstIPSet1 and BBstIPSet2 Settings for BBstFETScale = 0 (MAX20343B/E Only)

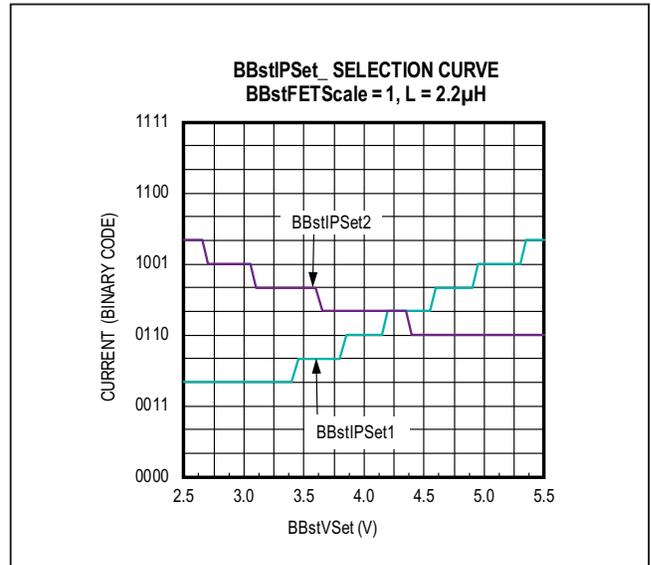


Figure 7. Recommended BBstIPSet1 and BBstIPSet2 Settings for BBstFETScale = 1 (on MAX20343B/E, and for either BBstFETScale setting for all other versions)

When  $BBstZCCmpDis = 1$  (register 0x01[4]), the zero crossing comparator is disabled and the buck-boost operates with only peak and valley current limits. In this configuration, the valley current limit acts as the zero crossing limit. In DCM, the valley limit is 0mA and is a true zero current crossing. In CCM, the peak and valley limits are automatically adjusted by the adaptive current control, so the effective zero current point might be larger than 0mA. This causes the MAX20343 to briefly enter Phase 4 each time the inductor current reaches the valley current threshold before transitioning to an inductor-charging phase. Setting  $BBstZCCmpDis = 0$  enables the zero current comparator and the buck-boost operates with peak, valley, and zero crossing current limits. While the adaptive current loop adjusts the peak and valley currents, the zero crossing limit is fixed at 0mA. In DCM, the regulator functions similarly to when  $BBstZCCmpDis = 1$ . However, in CCM, the valley current is greater than the zero crossing current, so the regulator bypasses Phase 4 and directly enters an inductor-charging phase when the inductor current reaches the valley current threshold.

Disabling the zero current crossing comparator reduces the buck-boost output ripple. Enabling the comparator improves efficiency in CCM by removing the Phase 4 stage in CCM that is otherwise present when  $BBstZCCmpDis = 1$ .

### Integrator Control Loop Disable

The MAX20343 contains an integrator in its control loop for normal operation. This integrator improves the load regulation for larger loads, but increases the transient response time. For applications where the output must quickly settle to a final regulation value to prevent noise injection during sensitive measurements (such as in PPG measurements), the integrator can be disabled so the regulator operates with a proportional-only control loop. The  $BBstIntegEn$  bit (register 0x04[2]) enables and disables the integrator to speed response time on load transients (integrator off) or to increase the load capacity (integrator on). Note that when the integrator is disabled output stability is only guaranteed up to the maximum output power for input voltages down to 2.5V. To operate at lower input voltages, the output capacitance must be increased.

### Input Operating Voltage

Operating at low input voltages enables a system to extract as much energy as possible from its energy source before shutting down. After startup and with  $SwoFrcIn = 0$ , and  $V_{OUT} \geq 3.3V$  (MAX20343B/E) or 3.2V (all other versions), the MAX20343 can operate to very low input voltages limited only by the amount of current that can be drawn effectively from the input. This allows

a system to run the MAX20343 well below the minimum startup voltage, albeit at a reduced power capability.

When the input voltage is low, the  $R_{ON}$  of the input p-channel MOSFET increases. To offset the inherent increase in resistance, an n-channel MOSFET is present in parallel with the input MOSFET. The n-channel MOSFET is only enabled when the input voltage falls below  $V_{IN\_UVLO\_F}$  to reduce switching losses at higher input voltages. In order to provide sufficient overdrive for the n-channel device, it is necessary to keep  $V_{OUT} \geq 3.3V$  (MAX20343B/E) or 3.2V (all other versions). Therefore, high power operation below  $V_{IN\_UVLO\_F}$  is only guaranteed if the output voltage is set to 3.3V (MAX20343B/E) or 3.2V (all other versions) or above.

### Output Operating Power and Other Optimizations

The MAX20343 is a highly flexible device with many operating modes that allows the user to optimize the performance for their application. For applications like driving an LED for on the wrist PPG, settling time to a steady-state voltage during a load transient is critical. In such cases, the user benefits from a proportional-only output response ( $BBstIntegEn = 0$ , disabled), which trades an increased steady-state load regulation error for speed of settling. On the other hand, some applications are not as sensitive to response time, but benefit from the lower steady-state load regulation error provided when the integrator is enabled ( $BBstIntegEn = 1$ , enabled).

The efficiency can also be optimized by selecting the  $BBstFETScale$  setting according to which load region should be the focus for efficiency. If the application should primarily be optimized for light-load efficiency, the  $BBstFETScale = 1$  (enabled) setting is preferable and vice-versa. Note that the improvement in efficiency at light loads with  $BBstFETScale = 1$  comes with the tradeoff of lower maximum output power, which should be a consideration when configuring the setting. A comparison of performances for each setting can be found in the [Typical Operating Characteristics](#) section.

Finally, the MAX20343 features an internal switchover circuit (configured by  $SwoFrcIn$ ), which manages the supply from which the internal circuitry of the buck-boost is driven. For applications where quiescent current is important and the primary operating mode is to boost the output, the switchover should be forced to the input ( $SwoFrcIn = 1$ ). This is because the quiescent current when  $SwoFrcIn = 0$  is drawn from the output, meaning that the input current is increased by the boost ratio and the efficiency of the conversion. However, in cases where a low input operating voltage must be supported, the  $SwoFrcIn = 0$  setting allows the input voltage to

drop much lower since the output voltage can be used to enhance the switching FETs of the buck-boost, keeping the on-resistance low. Note that when  $SwoFrcIN = 1$ , the buck-boost output automatically shuts down when  $V_{IN}$  falls below  $V_{IN\_UVLO\_F}$  (1.782V typ). Instead when  $SwoFrcIN = 0$  and  $V_{OUT} \geq 3.3V$  (MAX20343B/E) or 3.2V (all other versions), the output continues to run even when  $V_{IN}$  falls very low and is only disabled when the output voltage falls below  $V_{OUT\_UVLO\_F}$  or when the user disables the device. In this operating mode, the output power capabilities begin to decrease as the input voltage falls. To indicate that the input voltage has fallen to a critical level, the device generates an  $IN\_UVLO$  status and interrupt for the system, which means that  $V_{IN}$  has dropped below  $V_{IN\_UVLO\_F}$  and the source might be in a critical state. A comparison of performances for each setting can be found in the [Typical Operating Characteristics](#) section.

For each combination of the above settings, there are tradeoffs to consider. [Table 2](#) below gives a general outline of the basic characteristics to expect with a given configuration.

## Device Control

### I<sup>2</sup>C-Controlled

The I<sup>2</sup>C-controlled versions of MAX20343 enable system flexibility by providing an interface between the device and a host microcontroller. Different parameters of the regulator, such as output voltage the inductor peak current levels, FET scaling, etc., can be optimized in real time for any application. While default values are programmed by the factory, new values can be set in the I<sup>2</sup>C registers. For device versions with I<sup>2</sup>C control take special care to observe the default setting of  $BBstEn$  in [Table 3](#). Versions with  $BBstEn =$  disabled by default need to have another power supply present that allows the system to wake the buck-boost by I<sup>2</sup>C command. In versions of the MAX20343 with an I<sup>2</sup>C interface and an RSEL voltage selection pin, the default voltage selected by the RSEL resistor can be overwritten over I<sup>2</sup>C after the  $OutGood$  (register 0x05[1]) status goes high.

The full configuration settings and status information provided through this interface are detailed in the register descriptions. The slave address information for I<sup>2</sup>C-controlled versions of MAX20343 can be found in the [Applications Information](#) section.

### Single-Pin-Enable

In the single-pin-enabled, fixed-programming versions of MAX20343, all configuration settings excluding the output voltage are programmed by the factory and cannot be

modified in an application. Setting  $EN$  high turns on the regulator. Two status pins,  $INGOOD$  and  $PGOOD$ , signal that the input and output voltages are ready to support the full system power requirements, respectively.

When the  $FAST/RSEL$  pin of a single-pin-enabled MAX20343 is configured to  $RSEL$ , the output voltage is set by the the  $RSEL$  resistor at startup. When the  $FAST/RSEL$  pin is configured to  $FAST$ , the output voltage is set by the factory.

### Dynamic Voltage Scaling (DVS)

The output voltage of I<sup>2</sup>C-controlled MAX20343 devices can be changed at any point while the device is enabled without restarting the device. This feature is known as dynamic voltage scaling. DVS enables systems to operate at different voltage rails when the voltage or power requirements of the system change in different operating modes. By decreasing the voltage to the minimum value required by an operating mode, the overall system efficiency increases. The output voltage is set in  $BBstVSet[5:0]$  (register 0x02[5:0]).

### RSEL Voltage Setting

$RSEL$  is a unique, single-resistor output voltage selection method that minimizes quiescent current. Once power is applied at  $V_{IN}$  and the enable pin is brought high, the MAX20343 starts up and regulates to the minimum programmable voltage (2.5V). Once an internal  $PGOOD$  signal indicates that the voltage has reached an acceptable level, the device begins drawing up to 200 $\mu$ A from  $V_{IN}$  in order to read the resistor value on  $RSEL$ . This current is only present during the  $RSEL$  resistor detection time, typically 750 $\mu$ s. After the detection and output voltage programming period, the output increases to the set value. The output rise time is determined by the  $BBstRampEn$  setting [Figure 8](#) illustrates this startup sequence.

$RSEL$  has many benefits, including lower cost and smaller size. Only one resistor is needed versus the two resistors required in typical feedback connections. Another benefit of  $RSEL$  is that one regulator can be used in multiple projects with different output voltages just by changing a single standard 1% resistor. Lastly,  $RSEL$  eliminates wasting current continuously through feedback resistors for ultra-low power, battery-operated products. Select the  $RSEL$  resistor value by choosing the desired output voltage in [Table 1](#). Leaving  $RSEL$  open sets the output to the default voltage of the device (see [Table 3](#) for device configurations).

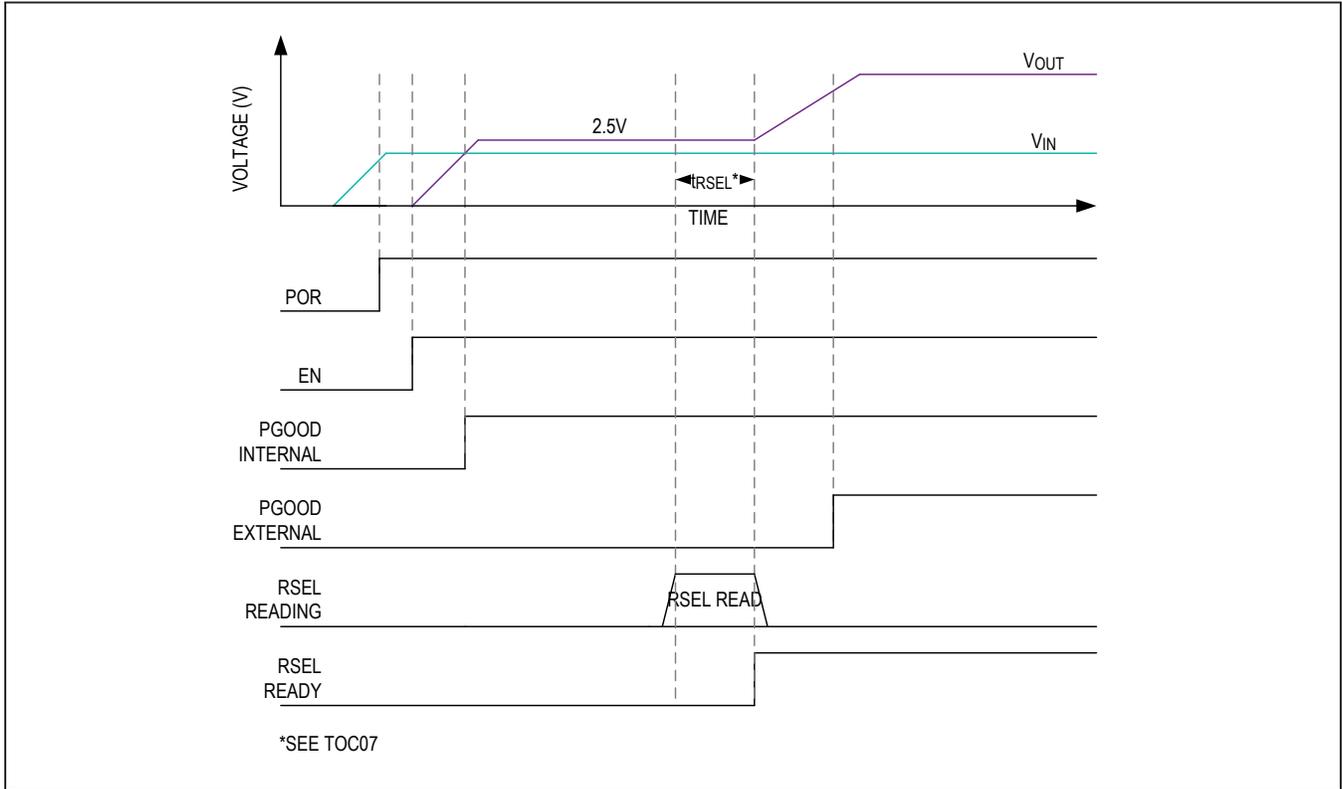


Figure 8. MAX20343 RSEL Startup Sequence

Table 1. RSEL Selection Table

OUTPUT VOLTAGE (V)	STD RES 1% (kΩ)
Default	OPEN
2.5	590
2.7	422
3.0	301
3.2	210
3.3	150
3.4	105
3.5	75
3.6	53.6
3.7	37.4
3.8	26.7
4.0	18.7
4.2	13.3
4.5	9.31
5.0	6.65
5.5	SHORT

Table 2. Characteristics and Device Settings

DEVICE VERSION	CHARACTERISTICS					DEVICE SETTINGS		
	MAX OUTPUT POWER ( $V_{IN} = V_{OUT} \geq 3.2V$ ) (W)	QUIESCENT CURRENT	OPTIMIZED FOR: STEADY-STATE LOAD REGULATION ERROR OR LOAD-TRANSIENT SETTLING TIME	EFFICIENCY OPTIMIZED CURRENT RANGE	INPUT OPERATING VOLTAGE $< V_{IN\_UVLO\_F}$	BBSTFETSCALE	BBSTINTEGEN	SWOFRGIN
MAX20343B/E	$\geq 2.8$	INCREASED IN BOOST MODE	SETTLING TIME	HIGH	YES ( $V_{OUT} \geq 3.3V$ )	0	0	0
ALL OTHER VERSIONS	$\geq 3.2$				YES ( $V_{OUT} \geq 3.2V$ )			
MAX20343B/E	$\geq 2.8$	LOWEST	SETTLING TIME	HIGH	NO	0	0	1
ALL OTHER VERSIONS	$\geq 3.2$							
MAX20343B/E	$\geq 3.5$	INCREASED IN BOOST MODE	LOAD REGULATION	HIGH	YES ( $V_{OUT} \geq 3.3V$ )	0	1	0
ALL OTHER VERSIONS					YES ( $V_{OUT} \geq 3.2V$ )			
ALL VERSIONS	$\geq 3.5$	LOWEST	LOAD REGULATION	HIGH	NO	0	1	1
MAX20343B/E	$\geq 1.6$	INCREASED IN BOOST MODE	SETTLING TIME	LOW/MEDIUM	YES ( $V_{OUT} \geq 3.3V$ )	1	0	0
ALL OTHER VERSIONS	$\geq 1.75$				YES ( $V_{OUT} \geq 3.2V$ )			
MAX20343B/E	$\geq 1.6$	LOWEST	SETTLING TIME	LOW/MEDIUM	NO	1	0	1
ALL OTHER VERSIONS	$\geq 1.75$							
MAX20343B/E	$\geq 1.75$	INCREASED IN BOOST MODE	LOAD REGULATION	LOW/MEDIUM	YES ( $V_{OUT} \geq 3.3V$ )	1	1	0
ALL OTHER VERSIONS					YES ( $V_{OUT} \geq 3.2V$ )			
ALL OTHER VERSIONS	$\geq 1.75$	LOWEST	LOAD REGULATION	LOW/MEDIUM	NO	1	1	1

## Register Map

## MAX20343

AD- DRESS	NAME	MSB							LSB
<b>USER</b>									
0x00	<a href="#">ChipID[7:0]</a>	ChipID[7:0]							
0x01	<a href="#">BBstCfg0[7:0]</a>	BBstEn	BBstRa mpEn	BBstFast	BBstZC- CmpDis	BBst- LowEMI	BBst- Mode	BBstAct Dsc	BBstPsv Dsc
0x02	<a href="#">BBstVSet[7:0]</a>	BBFHighSh[1:0]		BBstVSet[5:0]					
0x03	<a href="#">BBstISet[7:0]</a>	BBstIPSet2[3:0]				BBstIPSet1[3:0]			
0x04	<a href="#">BBstCfg1[7:0]</a>	FstC- mpEn	PasThr- Mode	SwoFrcIN	–	–	BBstInt- egEn	BBstI- PAdptDis	BBstFET Scale
0x05	<a href="#">Status[7:0]</a>	–	–	–	–	–	–	OutGood	InUVLO
0x06	<a href="#">Int[7:0]</a>	–	–	–	–	–	–	Out- GoodInt	InUV- LOInt
0x07	<a href="#">Mask[7:0]</a>	–	–	–	–	–	–	OutGood- IntM	InUV- LOIntM
0x50	<a href="#">LockMsk[7:0]</a>	–	–	–	–	–	–	–	BBLck
0x51	<a href="#">LockUnlock[7:0]</a>	PASSWD[7:0]							

## Register Details

## ChipID (0x00)

BIT	7	6	5	4	3	2	1	0	
Field	ChipID[7:0]								
Access Type	Read Only								
BITFIELD	BITS		DESCRIPTION						
ChipID	7:0		ChipID[7:0] indicates the version of the device in use.						

**BBstCfg0 (0x01)**

BIT	7	6	5	4	3	2	1	0
<b>Field</b>	BBstEn	BBstRampEn	BBstFast	BBstZCC-mpDis	BBstLowEMI	BBstMode	BBstActDsc	BBstPsvDsc
<b>Access Type</b>	Write, Read	Write, Read	Write, Read	Write, Read	Write, Read	Write, Read	Write, Read	Write, Read

BITFIELD	BITS	DESCRIPTION
BBstEn	7	Buck-Boost Enable 0 = Buck-boost disabled 1 = Buck-boost enabled
BBstRampEn	6	Buck-Boost Ramp Enable 0 = Output voltage setting transition is performed without intermediate steps 1 = Output voltage setting increases are performed with a digital ramp of 50mV every 50µs
BBstFast	5	Buck-Boost Pretrigger Mode Setting Increases the quiescent current of the buck-boost to improve output regulation during load transients. 0 = Normal, low quiescent current operation 1 = Fast response mode enabled. Quiescent current increased to 35µA (typ).
BBstZCCmpDis	4	Buck-Boost Zero-Crossing Comparator Disable. Latched internally, it can only be changed when BBstEn = 0 0 = Enabled 1 = Disabled
BBstLowEMI	3	Buck-Boost Low EMI Mode Increases the rise/fall time of HVLX/LVLX to reduce EMI, at the cost of efficiency. 0 = Normal operation 1 = Increase rise/fall time on HVLX/LVLX by 3x
BBstMode	2	Buck-Boost Operating Mode Configures the regulator to operate in buck-boost or buck-only mode. Latched internally, can only be changed while BBstEn = 0. 0 = Buck-boost mode 1 = Buck-only mode
BBstActDsc	1	Buck-Boost Active Discharge Control 0 = Buck-boost not actively discharged 1 = Buck-boost actively discharged on shutdown
BBstPsvDsc	0	Buck-Boost Passive Discharge Control 0 = Buck-boost not passively discharged 1 = Buck-boost passively discharged on shutdown

**BBstVSet (0x02)**

BIT	7	6	5	4	3	2	1	0
Field	BBFHighSh[1:0]		BBstVSet[5:0]					
Access Type	Write, Read		Write, Read					

BITFIELD	BITS	DESCRIPTION
BBFHighSh	7:6	<p>Buck-Boost <math>f_{HIGH}</math> Thresholds</p> <p>Selects the switching frequency threshold <math>f_{HIGH}</math>. If the buck-boost switching frequency exceeds the <math>f_{HIGH}</math> rising threshold, all the blocks are kept ON (<math>I_Q</math> is higher) until the frequency reaches the <math>f_{HIGH}</math> falling threshold. A small glitch on <math>V_{OUT}</math> can be present at the <math>f_{HIGH}</math> crossover.</p> <p>00 = 25kHz rising / 6.125kHz falling                      01 = 35kHz rising / 8.25kHz falling                      10 = 50kHz rising / 12.5kHz falling                      11 = 100kHz rising / 25kHz falling</p>
BBstVSet	5:0	<p>Buck-Boost Output Voltage Setting</p> <p>2.5V to 5.5V, Linear Scale, 50mV increments</p> <p>000000 = 2.5V                      000001 = 2.55V                      ...                      ≥111100 = 5.5V</p>

**BBstIPSet (0x03)**

BIT	7	6	5	4	3	2	1	0
Field	BBstIPSet2[3:0]				BBstIPSet1[3:0]			
Access Type	Write, Read				Write, Read			

BITFIELD	BITS	DESCRIPTION								
BBstIPSet2	7:4	<p>Buck-Boost Nominal Maximum Peak Current Setting See buck-boost operation section for a description of the peak current settings. 0mA (minimum <math>t_{ON}</math>) to 618.75mA, linear scale, 41.25mA increments for BBstFETScale = 0. 0mA (minimum <math>t_{ON}</math>) to 375mA, linear scale, 25mA increments for BBstFETScale = 1.</p> <table border="0"> <tr> <td>MAX20343B/E: BBstFETScale = 0: 0000 = 0mA (minimum <math>t_{ON}</math>) 0001 = 41.25mA ... 1111 = 618.75mA</td> <td>All other versions: BBstFETScale = 0: 0000 = 0mA (minimum <math>t_{ON}</math>) 0001 = 50mA ... 1111 = 750mA</td> </tr> <tr> <td>Recommended settings <math>V_{OUT} \leq 2.65V</math>: 577.50mA <math>2.65V &lt; V_{OUT} \leq 3.05V</math>: 536.25mA <math>3.05V &lt; V_{OUT} \leq 3.60V</math>: 495mA <math>3.60V &lt; V_{OUT} \leq 4.35V</math>: 453.75mA <math>V_{OUT} &gt; 4.35V</math>: 412.50mA</td> <td>Recommended settings <math>V_{OUT} \leq 2.65V</math>: 500mA (1010) <math>2.65V &lt; V_{OUT} \leq 3.05V</math>: 450mA (1001) <math>3.05V &lt; V_{OUT} \leq 3.60V</math>: 400mA (1000) <math>3.60V &lt; V_{OUT} \leq 4.35V</math>: 350mA (0111) <math>V_{OUT} &gt; 4.35V</math>: 300mA (0110)</td> </tr> <tr> <td>BBstFETScale = 1: 0000 = 0mA (minimum <math>t_{ON}</math>) 0001 = 25mA ... 1111 = 375mA</td> <td>BBstFETScale = 1: 0000 = 0mA (minimum <math>t_{ON}</math>) 0001 = 25mA ... 1111 = 375mA</td> </tr> <tr> <td>Recommended settings <math>V_{OUT} \leq 2.65V</math>: 250mA <math>2.65V &lt; V_{OUT} \leq 3.05V</math>: 225mA <math>3.05V &lt; V_{OUT} \leq 3.60V</math>: 200mA <math>3.60V &lt; V_{OUT} \leq 4.35V</math>: 175mA <math>V_{OUT} &gt; 4.35V</math>: 150mA</td> <td>Recommended settings <math>V_{OUT} \leq 2.65V</math>: 250mA (1010) <math>2.65V &lt; V_{OUT} \leq 3.05V</math>: 225mA (1001) <math>3.05V &lt; V_{OUT} \leq 3.60V</math>: 200mA (1000) <math>3.60V &lt; V_{OUT} \leq 4.35V</math>: 175mA (0111) <math>V_{OUT} &gt; 4.35V</math>: 150mA (0110)</td> </tr> </table>	MAX20343B/E: BBstFETScale = 0: 0000 = 0mA (minimum $t_{ON}$ ) 0001 = 41.25mA ... 1111 = 618.75mA	All other versions: BBstFETScale = 0: 0000 = 0mA (minimum $t_{ON}$ ) 0001 = 50mA ... 1111 = 750mA	Recommended settings $V_{OUT} \leq 2.65V$ : 577.50mA $2.65V < V_{OUT} \leq 3.05V$ : 536.25mA $3.05V < V_{OUT} \leq 3.60V$ : 495mA $3.60V < V_{OUT} \leq 4.35V$ : 453.75mA $V_{OUT} > 4.35V$ : 412.50mA	Recommended settings $V_{OUT} \leq 2.65V$ : 500mA (1010) $2.65V < V_{OUT} \leq 3.05V$ : 450mA (1001) $3.05V < V_{OUT} \leq 3.60V$ : 400mA (1000) $3.60V < V_{OUT} \leq 4.35V$ : 350mA (0111) $V_{OUT} > 4.35V$ : 300mA (0110)	BBstFETScale = 1: 0000 = 0mA (minimum $t_{ON}$ ) 0001 = 25mA ... 1111 = 375mA	BBstFETScale = 1: 0000 = 0mA (minimum $t_{ON}$ ) 0001 = 25mA ... 1111 = 375mA	Recommended settings $V_{OUT} \leq 2.65V$ : 250mA $2.65V < V_{OUT} \leq 3.05V$ : 225mA $3.05V < V_{OUT} \leq 3.60V$ : 200mA $3.60V < V_{OUT} \leq 4.35V$ : 175mA $V_{OUT} > 4.35V$ : 150mA	Recommended settings $V_{OUT} \leq 2.65V$ : 250mA (1010) $2.65V < V_{OUT} \leq 3.05V$ : 225mA (1001) $3.05V < V_{OUT} \leq 3.60V$ : 200mA (1000) $3.60V < V_{OUT} \leq 4.35V$ : 175mA (0111) $V_{OUT} > 4.35V$ : 150mA (0110)
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BITFIELD	BITS	DESCRIPTION		
BBstIPSet1	3:0	<p>Buck-boost nominal peak current setting 1 Nominal peak current when charging inductor between <math>V_{IN}</math> and GND. See buck-boost operation section for a description of the peak current settings. 0mA (minimum <math>t_{ON}</math>) to 618.75mA, linear scale, 41.25mA increments for BBstFETScale = 0. 0mA (minimum <math>t_{ON}</math>) to 375mA, linear scale, 25mA increments for BBstFETScale = 1.</p> <table border="0"> <tr> <td style="vertical-align: top;"> <p>MAX20343B/E: BBstFETScale = 0: 0000 = 0mA (minimum <math>t_{ON}</math>) 0001 = 41.25mA ... 1111 = 618.75mA</p> <p>Recommended settings <math>V_{OUT} \leq 4.55V</math>: 330mA <math>4.55V &lt; V_{OUT} \leq 4.90V</math>: 412.50mA <math>4.90V &lt; V_{OUT} \leq 5.30V</math>: 453.75mA <math>V_{OUT} &gt; 5.3V</math>: 495mA</p> <p>BBstFETScale = 1: 0000 = 0mA (minimum <math>t_{ON}</math>) 0001 = 25mA ... 1111 = 375mA</p> <p>Recommended settings <math>V_{OUT} \leq 3.40V</math>: 100mA <math>3.40V &lt; V_{OUT} \leq 3.80V</math>: 125mA <math>3.80V &lt; V_{OUT} \leq 4.15V</math>: 150mA <math>4.15V &lt; V_{OUT} \leq 4.55V</math>: 175mA <math>4.55V &lt; V_{OUT} \leq 4.90V</math>: 200mA <math>4.90V &lt; V_{OUT} \leq 5.30V</math>: 225mA <math>V_{OUT} &gt; 5.30V</math>: 250mA</p> </td> <td style="vertical-align: top;"> <p>All other versions: BBstFETScale = 0: 0000 = 0mA (minimum <math>t_{ON}</math>) 0001 = 50mA ... 1111 = 750mA</p> <p>Recommended settings <math>V_{OUT} \leq 3.40V</math>: 200mA (0100) <math>3.40V &lt; V_{OUT} \leq 3.80V</math>: 250mA (0101) <math>3.80V &lt; V_{OUT} \leq 4.15V</math>: 300mA (0110) <math>4.15V &lt; V_{OUT} \leq 4.55V</math>: 350mA (0111) <math>4.55V &lt; V_{OUT} \leq 4.90V</math>: 400mA (1000) <math>4.90V &lt; V_{OUT} \leq 5.30V</math>: 450mA (1001) <math>V_{OUT} &gt; 5.30V</math>: 500mA (1010)</p> <p>BBstFETScale = 1: 0000 = 0mA (minimum <math>t_{ON}</math>) 0001 = 25mA ... 1111 = 375mA</p> <p>Recommended settings <math>V_{OUT} \leq 3.40V</math>: 100mA (0100) <math>3.40V &lt; V_{OUT} \leq 3.80V</math>: 125mA (0101) <math>3.80V &lt; V_{OUT} \leq 4.15V</math>: 150mA (0110) <math>4.15V &lt; V_{OUT} \leq 4.55V</math>: 175mA (0111) <math>4.55V &lt; V_{OUT} \leq 4.90V</math>: 200mA (1000) <math>4.90V &lt; V_{OUT} \leq 5.30V</math>: 225mA (1001) <math>V_{OUT} &gt; 5.30V</math>: 250mA (1010)</p> </td> </tr> </table>	<p>MAX20343B/E: BBstFETScale = 0: 0000 = 0mA (minimum <math>t_{ON}</math>) 0001 = 41.25mA ... 1111 = 618.75mA</p> <p>Recommended settings <math>V_{OUT} \leq 4.55V</math>: 330mA <math>4.55V &lt; V_{OUT} \leq 4.90V</math>: 412.50mA <math>4.90V &lt; V_{OUT} \leq 5.30V</math>: 453.75mA <math>V_{OUT} &gt; 5.3V</math>: 495mA</p> <p>BBstFETScale = 1: 0000 = 0mA (minimum <math>t_{ON}</math>) 0001 = 25mA ... 1111 = 375mA</p> <p>Recommended settings <math>V_{OUT} \leq 3.40V</math>: 100mA <math>3.40V &lt; V_{OUT} \leq 3.80V</math>: 125mA <math>3.80V &lt; V_{OUT} \leq 4.15V</math>: 150mA <math>4.15V &lt; V_{OUT} \leq 4.55V</math>: 175mA <math>4.55V &lt; V_{OUT} \leq 4.90V</math>: 200mA <math>4.90V &lt; V_{OUT} \leq 5.30V</math>: 225mA <math>V_{OUT} &gt; 5.30V</math>: 250mA</p>	<p>All other versions: BBstFETScale = 0: 0000 = 0mA (minimum <math>t_{ON}</math>) 0001 = 50mA ... 1111 = 750mA</p> <p>Recommended settings <math>V_{OUT} \leq 3.40V</math>: 200mA (0100) <math>3.40V &lt; V_{OUT} \leq 3.80V</math>: 250mA (0101) <math>3.80V &lt; V_{OUT} \leq 4.15V</math>: 300mA (0110) <math>4.15V &lt; V_{OUT} \leq 4.55V</math>: 350mA (0111) <math>4.55V &lt; V_{OUT} \leq 4.90V</math>: 400mA (1000) <math>4.90V &lt; V_{OUT} \leq 5.30V</math>: 450mA (1001) <math>V_{OUT} &gt; 5.30V</math>: 500mA (1010)</p> <p>BBstFETScale = 1: 0000 = 0mA (minimum <math>t_{ON}</math>) 0001 = 25mA ... 1111 = 375mA</p> <p>Recommended settings <math>V_{OUT} \leq 3.40V</math>: 100mA (0100) <math>3.40V &lt; V_{OUT} \leq 3.80V</math>: 125mA (0101) <math>3.80V &lt; V_{OUT} \leq 4.15V</math>: 150mA (0110) <math>4.15V &lt; V_{OUT} \leq 4.55V</math>: 175mA (0111) <math>4.55V &lt; V_{OUT} \leq 4.90V</math>: 200mA (1000) <math>4.90V &lt; V_{OUT} \leq 5.30V</math>: 225mA (1001) <math>V_{OUT} &gt; 5.30V</math>: 250mA (1010)</p>
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**BBstCfg1 (0x04)**

BIT	7	6	5	4	3	2	1	0
Field	FstCmpEn	PasThr-Mode	SwoFrcIN	–	–	BBstIntegEn	BBstIPAdpt-Dis	BBst-FETScale
Access Type	Write, Read	Write, Read	Write, Read	–	–	Write, Read	Write, Read	Write, Read

BITFIELD	BITS	DESCRIPTION
FstCmpEn	7	FAST Comparator Enable The FAST mode comparator is enabled by the logical AND of the FAST pin and FstCmpEn. 0 = FAST pin does not control FAST mode 1 = FAST pin can set the device into FAST mode
PasThrMode	6	Pass Through Mode Bypasses the regulator to connect $V_{OUT}$ to $V_{IN}$ . This can only be enabled when $BBstEn = 0$ (register 0x01). 0 = Pass Through Mode disabled 1 = Pass Through Mode enabled. Enable only when $BBstEn = 0$ .
SwoFrcIN	5	Force Switch-Over Controls how the device powers the internal circuitry. 0 = Switch-over supply forced to $V_{OUT}$ when $V_{OUT} > V_{OUT\_UVLO\_R}$ . 1 = Switch-over supply forced to $V_{IN}$ .
BBstIntegEn	2	Buck-Boost Integrator Enable The Integrator can be disabled to improve settling time on load transients at the cost of load regulation error. Latched internally, it can only be changed when $BBstEn = 0$ . 0 = Integrator disabled 1 = Integrator enabled
BBstIPAdptDis	1	Adaptive Peak/Valley Current Adjustment Disable 0 = Enabled 1 = Disabled, peak current fixed to the values set by $BBstIPSet1$ and $BBstIPSet2$ . Valley current is fixed to 0mA. This setting is equivalent to forcing discontinuous conduction mode and greatly diminishes the output power capability of the part. Generally this is not a recommended setting.
BBstFETScale	0	FET Scale Reduces FET sizes by a factor of 2. This setting can be used to optimize efficiency for lighter loads if it is acceptable to support lower maximum output power. If $BBstFETScale = 0$ , the part requires a 1 $\mu$ H inductor and at least twice the derated capacitance in <a href="#">Figure 9</a> . If $BBstFETScale = 1$ , the part requires a 2.2 $\mu$ H inductor and at least the derated capacitance in <a href="#">Figure 9</a> . Latched internally, it can only be changed when $BBstEn = 0$ . 0 = FET scaling disabled 1 = FET scaling enabled

**Status (0x05)**

BIT	7	6	5	4	3	2	1	0
Field	–	–	–	–	–	–	OutGood	InUVLO
Access Type	–	–	–	–	–	–	Read Only	Read Only

BITFIELD	BITS	DESCRIPTION
OutGood	1	Status of Output Voltage 0 = Output has not reached full power capability 1 = Output voltage is high enough to support full power capability
InUVLO	0	Status register showing whether input voltage is low enough to enable parallel input NMOS. 0 = $V_{IN}$ high enough for full power operation 1 = Power may be limited due to low $V_{IN}$

**Int (0x06)**

BIT	7	6	5	4	3	2	1	0
Field	–	–	–	–	–	–	OutGoodInt	InUVLOInt
Access Type	–	–	–	–	–	–	Read Only	Read Only

BITFIELD	BITS	DESCRIPTION
OutGoodInt	1	Change in OutGood caused an interrupt
InUVLOInt	0	Change in InUVLO caused an interrupt

**Mask (0x07)**

BIT	7	6	5	4	3	2	1	0
Field	–	–	–	–	–	–	OutGood-IntM	InUVLOIntM
Access Type	–	–	–	–	–	–	Write, Read	Write, Read

BITFIELD	BITS	DESCRIPTION
OutGoodIntM	1	OutGoodIntM masks the OutGoodInt interrupt. 0 = Not masked 1 = Masked
InUVLOIntM	0	InUVLOIntM masks the InUVLOInt interrupt. 0 = Not masked 1 = Masked

**LockMsk (0x50)**

BIT	7	6	5	4	3	2	1	0
Field	–	–	–	–	–	–	–	BBLck
Access Type	–	–	–	–	–	–	–	Write, Read

BITFIELD	BITS	DESCRIPTION
BBLck	0	Lock Mask for Buck-Boost Registers 0 = Buck-Boost Registers not masked from locking/unlocking 1 = Buck-Boost Registers masked from locking/unlocking

**LockUnlock (0x51)**

BIT	7	6	5	4	3	2	1	0
Field	PASSWD[7:0]							
Access Type	Write, Read							

BITFIELD	BITS	DESCRIPTION
PASSWD	7:0	Lock/Unlock Password Write 0xAA with BBLck unmasked to lock the BBstVSet[5:0] field Write 0x55 with BBLck unmasked to unlock the BBstVSet[5:0] field

## Applications Information

### Input and Output Capacitance

The MAX20343 is designed to be compatible with small case-size ceramic capacitors. As such, the device has low-input and low-output capacitance requirements to accommodate the steep voltage derating of 0603 and 0402 (imperial) capacitors. The sample derating curve in [Figure 9](#) presents the minimum capacitance required at IN and OUT. To ensure stability and low noise, the capacitance on IN should be the minimum of 5 $\mu$ F and the value of [Figure 9](#) at the lowest expected  $V_{IN}$ . The capacitance on OUT should be equal to the value of [Figure 9](#) at the highest expected  $V_{OUT}$  for BBstFETScale = 1 and twice that value for BBstFETScale = 0.

### Inductor Selection

Inductor selection for the MAX20343 should be optimized for the intended application. A 2.2 $\mu$ H inductor value is required when FET scaling is enabled (BBstFETScale = 1) while 1 $\mu$ H is required when FET scaling is disabled (BBstFETScale = 0). Aside from the inductor value physical size, DC resistance (DCR), maximum average current, and saturation current are the primary factors to consider. The maximum average inductor current is obtained using the following equation:

$$I_{L\_MAX} = \frac{V_{OUT\_MAX} \times I_{OUT\_MAX}}{\eta \times V_{IN\_MIN}}$$

where,

$V_{OUT\_MAX}$  = Maximum expected operating voltage,

$I_{OUT\_MAX}$  = Maximum expected output current,

$V_{IN\_MIN}$  = Minimum expected operating input voltage,

$\eta$  = Expected worst-case efficiency in the minimum input voltage and maximum output power case (see the [Typical Operating Characteristics](#) for help in estimating efficiency).

The average inductor current calculated above dictates the required maximum average current for temperature rise on the inductor. In order to determine the required inductor

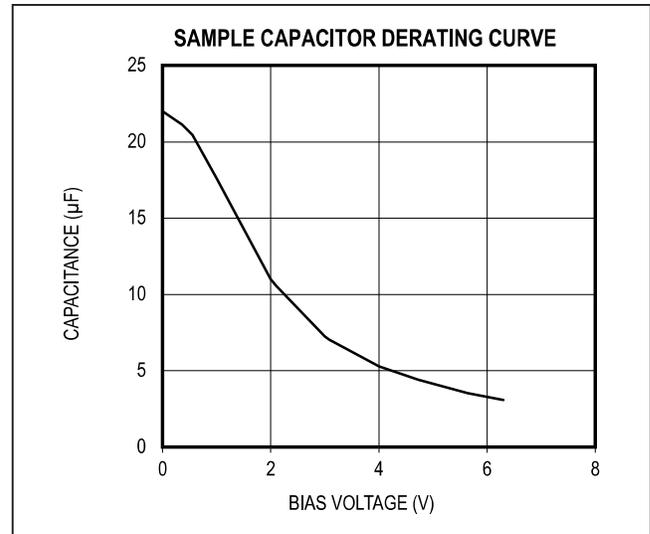


Figure 9. Capacitor Derating for Input and Output Capacitance

saturation current, the peak current must be calculated. The peak current for this converter can be calculated as:

$$I_{L\_PEAK} = I_{L\_MAX} + (1.1 \times \text{BBstIPSet1})$$

where BBstIPSet1 is the peak current setting described in register 0x03. Then selecting an inductor, one primary factor in achieving high efficiency is the DCR of the inductor. For maximum efficiency, select an inductor with the lowest DCR possible in the required package size. Another factor to consider is magnetic losses. Generally magnetic losses are lower in inductors with larger physical size and/or higher saturation current ratings. In most cases, ferrite inductors should be avoided as they tend to exhibit poor AC characteristics, especially in discontinuous conduction mode (DCM).

### I<sup>2</sup>C Interface

The MAX20343 contains an I<sup>2</sup>C-compatible interface for data communication with a host controller (SCL and SDA). On MAX20343B/E interface requires a minimum 400kHz clock frequency and supports frequencies up to 680kHz. All other versions of the MAX20343 can support I<sup>2</sup>C frequencies from 0kHz to 680kHz. SCL and SDA require pul-lup resistors that are connected to a positive supply.

**Slave Address**

The MAX20343B/E 7-bit slave address is 0b0101000 (0x28) plus the Read/Write bit. Set the Read/Write bit high to configure the MAX20343B/E to read mode (0x51). Set the Read/Write bit low to configure the MAX20343B/E to write mode (0x50). For all other versions of the MAX20343, the slave address is configured at the factory by the SlaveAddr bit to be either 0b1101000 (0x68) plus the Read/Write bit or 0b1101100 (0x6C) plus the Read/Write bit. For versions with the 7-bit slave address 0x68 Set the Read/Write bit high to configure the MAX20343 to read mode (0xD1) or set the Read/Write bit low to configure the MAX20343 to write mode (0xD0). For versions with the 7-bit slave address 0x6C Set the Read/Write bit high to configure the MAX20343 to read mode (0xD8) or set the Read/Write bit low to configure the MAX20343 to write mode (0xD9). See SlaveAddr in Table 3 for the slave address for a given part number. The address is the first byte of information sent to the MAX20343 after the START condition.

**Start, Stop, and Repeated Start Conditions**

When writing to the MAX20343 using I<sup>2</sup>C, the master sends a START condition (S) followed by the MAX20343 I<sup>2</sup>C write address. After the address, the master sends the register address of the register that is to be programmed. The master then ends communication by issuing a STOP condition (P) to relinquish control of the bus, or a REPEATED START condition (Sr) to communicate to another I<sup>2</sup>C slave. See Figure 10.

**Bit Transfer**

One data bit is transferred on the rising edge of each SCL clock cycle. The data on SDA must remain stable during the high period of the SCL clock pulse. Changes in SDA

while SCL is high and stable are considered control signals (see the *Start, Stop, and Repeated Start Conditions* section). Both SDA and SCL remain high when the bus is not active.

**Single-Byte Write**

In this operation, the master sends an address and two data bytes to the slave device (Figure 11). The following procedure describes the single byte write operation:

- The master sends a START condition.
- The master sends the 7-bit slave address plus a write bit (low).
- The addressed slave asserts an ACK on the data line.
- The master sends the 8-bit register address.
- The slave asserts an ACK on the data line only if the address is valid (NACK if not).
- The master sends 8 data bits.
- The slave asserts an ACK on the data line.
- The master generates a STOP condition.

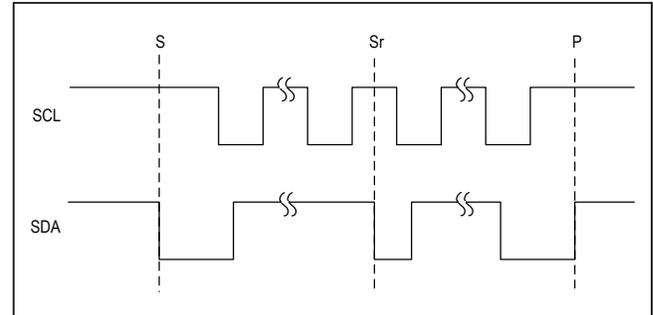


Figure 10. I<sup>2</sup>C START, STOP, and REPEATED START Conditions

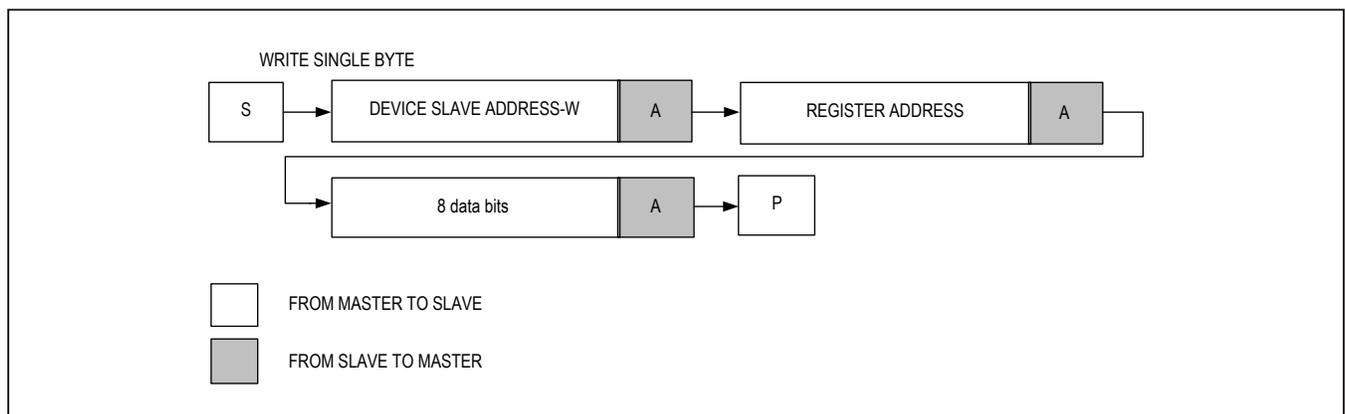


Figure 11. Write Byte Sequence

**Burst Write**

In this operation, the master sends an address and multiple data bytes to the slave device (Figure 12). The slave device automatically increments the register address after each data byte is sent, unless the register being accessed is 0x00, in which case the register address remains the same. The following procedure describes the burst write operation:

- The master sends a START condition.
- The master sends the 7-bit slave address plus a write bit (low).
- The addressed slave asserts an ACK on the data line.
- The master sends the 8-bit register address.
- The slave asserts an ACK on the data line only if the address is valid (NACK if not).
- The master sends 8 data bits.
- The slave asserts an ACK on the data line.
- Repeat 6 and 7 N-1 times.
- The master generates a STOP condition.

**Single Byte Read**

In this operation, the master sends an address plus two data bytes and receives one data byte from the slave device (Figure 13). The following procedure describes the single byte read operation:

- The master sends a START condition.
- The master sends the 7-bit slave address plus a write bit (low).
- The addressed slave asserts an ACK on the data line.
- The master sends the 8-bit register address.
- The slave asserts an ACK on the data line only if the address is valid (NACK if not).
- The master sends a REPEATED START condition.
- The master sends the 7-bit slave address plus a read bit (high).
- The addressed slave asserts an ACK on the data line.
- The slave sends 8 data bits.
- The master asserts a NACK on the data line.
- The master generates a STOP condition.

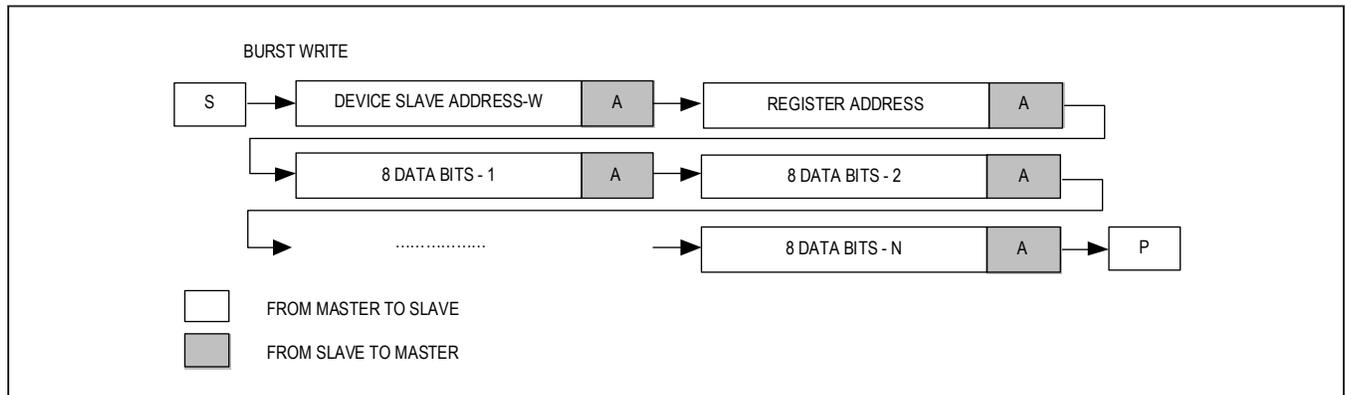


Figure 12. Burst Write Sequence

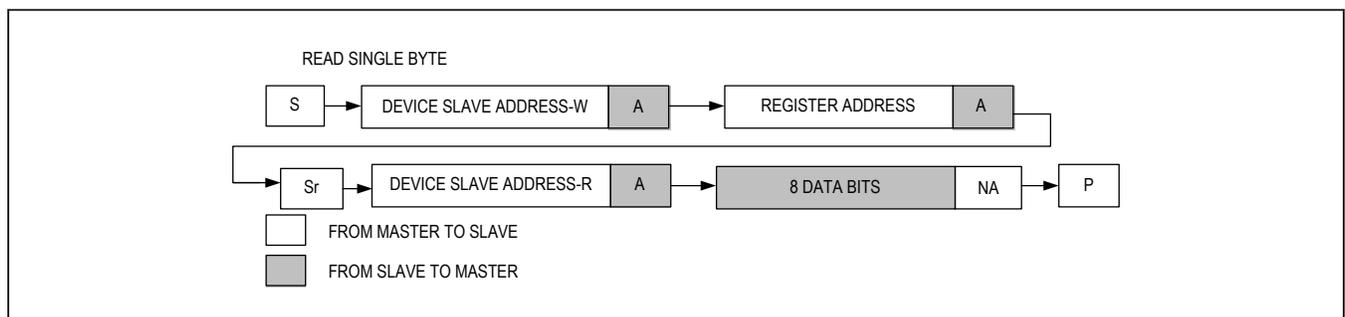


Figure 13. Read Byte Sequence

**Burst Read**

In this operation, the master sends an address plus two data bytes and receives multiple data bytes from the slave device (Figure 14). The following procedure describes the burst byte read operation:

- The master sends a START condition.
- The master sends the 7-bit slave address plus a write bit (low).
- The addressed slave asserts an ACK on the data line.
- The master sends the 8-bit register address.
- The slave asserts an ACK on the data line only if the address is valid (NACK if not).
- The master sends a REPEATED START condition.
- The master sends the 7-bit slave address plus a read bit (high).
- The slave asserts an ACK on the data line.

- The slave sends 8 data bits.
- The master asserts an ACK on the data line.
- Repeat 9 and 10 N-2 times.
- The slave sends the last 8 data bits.
- The master asserts a NACK on the data line.
- The master generates a STOP condition.

**Acknowledge Bits**

Data transfers are acknowledged with an acknowledge bit (ACK) or a not-acknowledge bit (NACK). Both the master and the MAX20343 generate ACK bits. To generate an ACK, pull SDA low before the rising edge of the ninth clock pulse and hold it low during the high period of the ninth clock pulse (Figure 15). To generate a NACK, leave SDA high before the rising edge of the ninth clock pulse and leave it high for the duration of the ninth clock pulse. Monitoring for NACK bits allows for detection of unsuccessful data transfers.

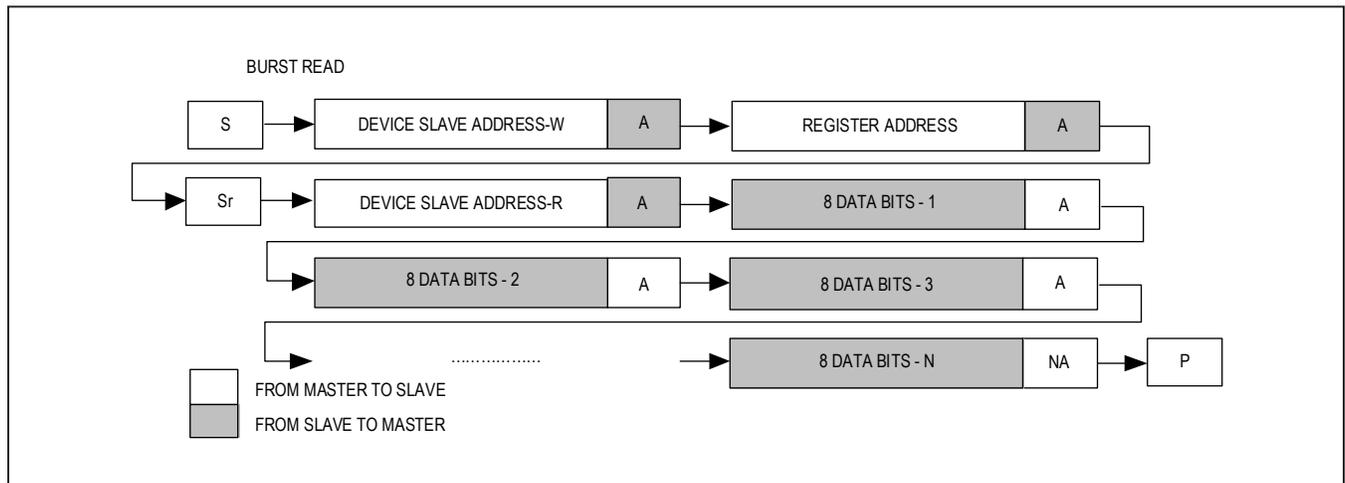


Figure 14. Burst Read Sequence

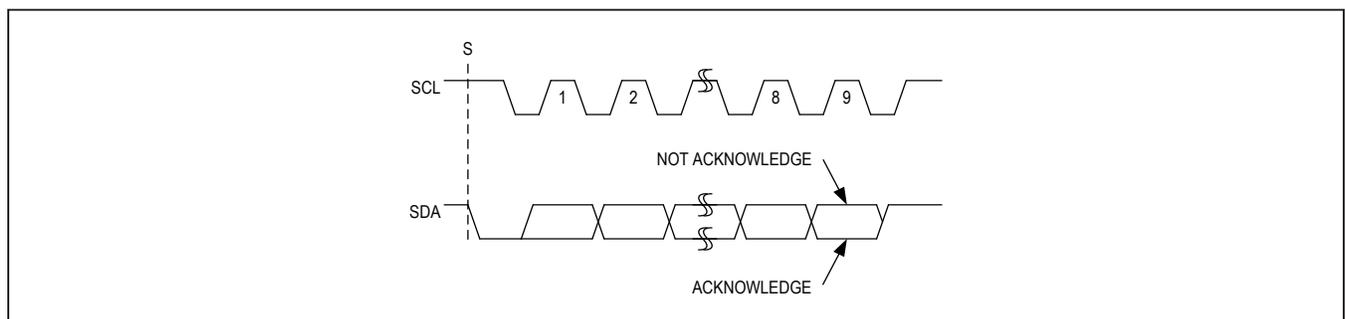


Figure 15. Acknowledge Bits

**Table 3. Register Bit Default Values**

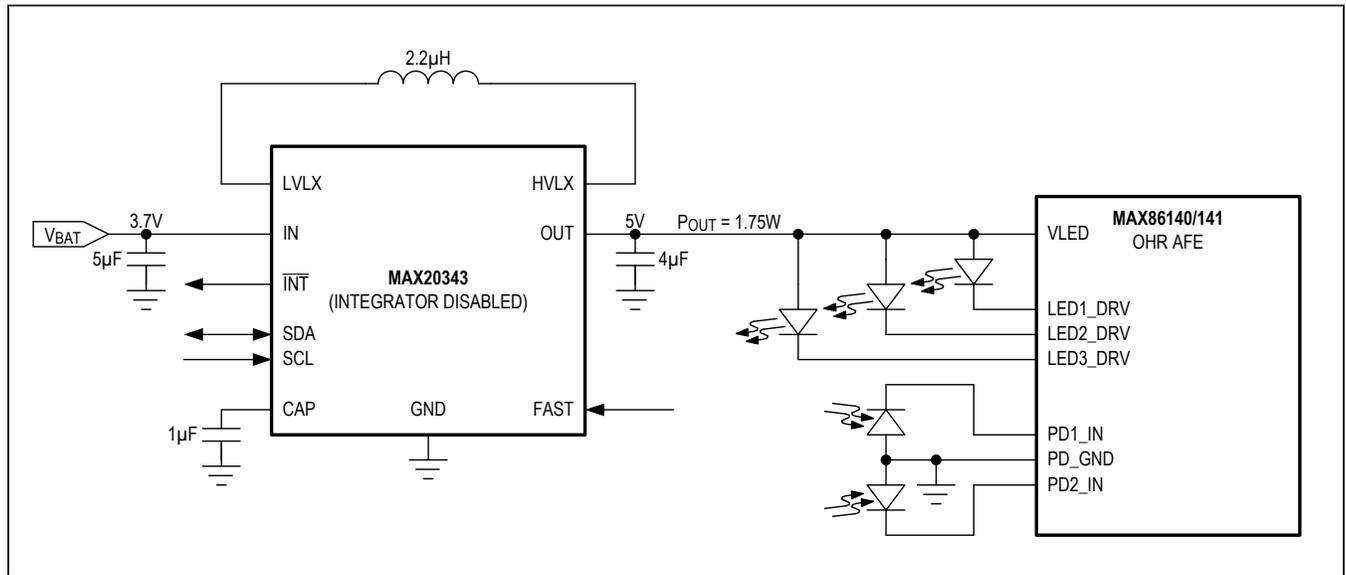
REGISTER BITS	DEVICE			
	MAX20343B	MAX20343E	MAX20343F	MAX20343G
BBstEn	Disabled	Disabled	Enabled	Disabled
BBstRampEn	Single Step	Single Step	Single Step	Single Step
BBstFast	Low I <sub>Q</sub> Mode	Low I <sub>Q</sub> Mode	Low I <sub>Q</sub> Mode	Low I <sub>Q</sub> Mode
BBstZCCmpDis	ZCC Disabled	ZCC Disabled	ZCC Disabled	ZCC Disabled
BBstLowEMI	High Efficiency	High Efficiency	High Efficiency	High Efficiency
BBstMode	Buck-Boost	Buck-Boost	Buck-Boost	Buck-Boost
BBstActDsc	Active Discharge on Shutdown (50ms)	Active Discharge on Shutdown (50ms)	Active Discharge on Shutdown (50ms)	Active Discharge on Shutdown (50ms)
BBstPsvDsc	Passive Discharge in Shutdown	Passive Discharge in Shutdown	Passive Discharge in Shutdown	Passive Discharge in Shutdown
BBstFHighSh[1:0]	100kHz/25kHz	100kHz/25kHz	100kHz/25kHz	100kHz/25kHz
SwoFrcIN	Switch-Over Forced to V <sub>OUT</sub> when OutGood = 1	Switch-Over Forced to V <sub>IN</sub>	Switch-Over Forced to V <sub>OUT</sub> when OutGood = 1	Switch-Over Forced to V <sub>OUT</sub> when OutGood = 1
BBstVSet[5:0]	3.20V	5.00V	3.30V	3.20V
BBstIntegEn	Disable Integrator	Disable Integrator	Enable Integrator	Disable Integrator
BBstIPAdptDis	Adaptive Peak Current Enabled	Adaptive Peak Current Enabled	Adaptive Peak Current Enabled	Adaptive Peak Current Enabled
BBstFETScale	FET Scaling Enabled	FET Scaling Enabled	FET Scaling Disabled	FET Scaling Enabled
FastRSELMode	FAST	FAST	FAST	FAST
EnI2CMode	I <sup>2</sup> C Control	I <sup>2</sup> C Control	I <sup>2</sup> C Control	I <sup>2</sup> C Control
BBstIPSet1[3:0]	100mA	225mA	400mA	100mA
BBstIPSet2[3:0]	BBstIPSet1 + 200mA	BBstIPSet1 + 150mA	BBstIPSet1 + 600mA	BBstIPSet1 + 200mA
BBstIP1SS[3:0]	375mA	375mA	750mA	375mA
BBstIP2SS[3:0]	BBstIPSet1 + 75mA	BBstIPSet1 + 75mA	BBstIPSet1 + 150mA	BBstIPSet1 + 75mA
Slave_Addr	0x50/0x51	0x50/0x51	0xD0/0xD1	0xD0/0xD1

**Table 4. Register Default Values**

REGISTER	NAME	DEVICE			
		MAX20343B	MAX20343E	MAX20343F	MAX20343G
0x00	ChipID	0x01	0x01	0x01	0x02
0x01	BBstCfg0	0x13	0x13	0x93	0x13
0x02	BBstVSet	0xCE	0xF2	0xD0	0xCE
0x03	BBstISet	0x84	0x69	0xC8	0x84
0x04	BBstCfg1	0x81	0xA1	0x84	0x81
0x05	Status	0x00	0x00	0x02	0x00
0x06	Int	0x00	0x00	0x00	0x00
0x07	Mask	0x03	0x03	0x03	0x03
0x50	LockMsk	0x01	0x01	0x01	0x01
0x51	LockUnlock	0xFF	0xFF	0xFF	0xFF

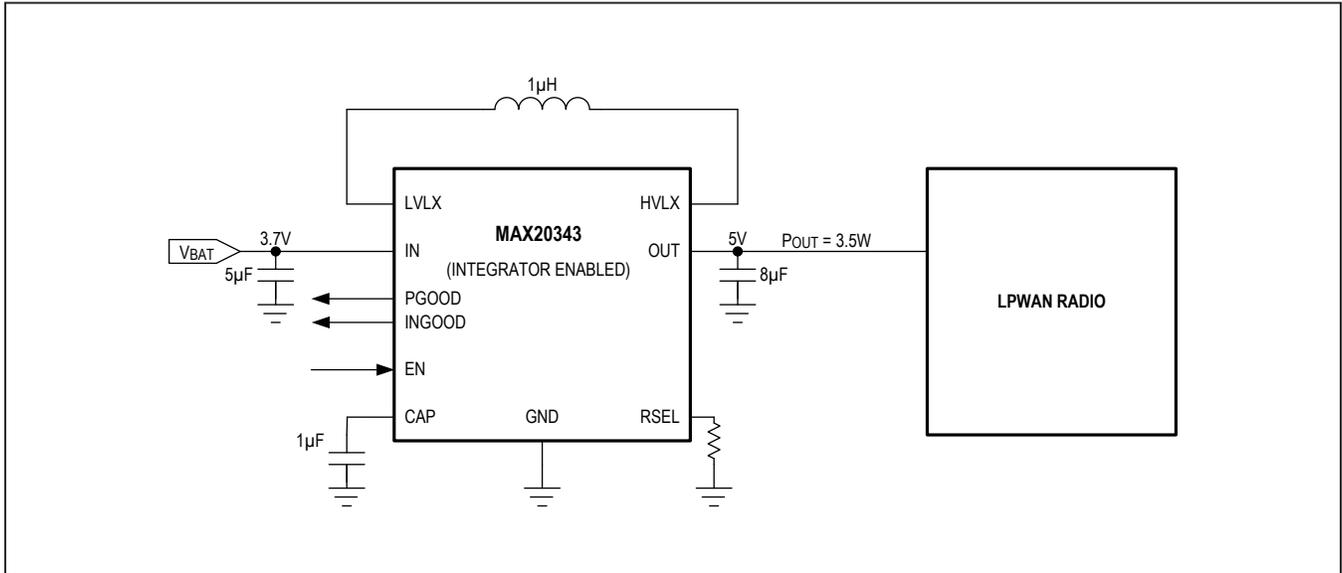
**Typical Application Circuits**

**Optical Heart Rate LED Supply**



Typical Application Circuits (continued)

LPWAN Radio Supply



Ordering Information

PART NUMBER	TEMP RANGE	PIN-PACKAGE
MAX20343BEFC+*	-40°C to +85°C	12 FC2QFN
MAX20343BEFC+T*	-40°C to +85°C	12 FC2QFN
MAX20343EEFC+*	-40°C to +85°C	12 FC2QFN
MAX20343EEFC+T*	-40°C to +85°C	12 FC2QFN
MAX20343GEFC+*	-40°C to +85°C	12 FC2QFN
MAX20343GEFC+T*	-40°C to +85°C	12 FC2QFN
MAX20343BEWE+	-40°C to +85°C	16 WLP
MAX20343BEWE+T	-40°C to +85°C	16 WLP
MAX20343EEWE+	-40°C to +85°C	16 WLP
MAX20343EEWE+T	-40°C to +85°C	16 WLP
MAX20343FEWE+ *	-40°C to +85°C	16 WLP
MAX20343FEWE+T *	-40°C to +85°C	16 WLP
MAX20343GEWE+	-40°C to +85°C	16 WLP
MAX20343GEWE+T	-40°C to +85°C	16 WLP

+ Denotes a lead(Pb)-free/RoHS-compliant package.

T = Tape-and-reel.

\*Future product—contact factory for availability.

See Table 3 for specific device settings and defaults to select a part.

## Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	3/19	Initial release	—
1	3/19	Corrected typos; updated BBstFETScale Bit Description (and corrected typo), and added future product designation to MAX20343EEWE+ and MAX20343EEWE+T	19, 21, 25, 34
2	4/19	Updated the <i>General Description, Benefits and Features, Absolute Maximum Ratings, Package Information, Pin Configuration, Pin Description, Buck-Boost Mode</i> and <i>Inductor Peak and Valley Current Limits</i> sections, and Register Map and BBstCfg0 (0x01) tables; added MAX20343BEFC+ and MAX20343BEFC+T as future parts to the <i>Ordering Information</i> table	1, 3, 12–13, 16, 18, 20–21, 34
3	6/19	Removed future part designation from MAX20343EEWE+ and MAX20343EEWE+T in the <i>Ordering Information</i> table	34
4	1/20	Updated the <i>General Description, Benefits and Features, Electrical Characteristics, Typical Operating Characteristics, Pin Description, Startup Voltage, Architectural Design, Switching Phases, Buck-Boost Mode, Buck-Only Mode, Inductor Peak and Valley Current Limits, Integrator Control Loop Disable, Input Operating Voltage, I<sup>2</sup>C-Controlled, Input and Output Capacitance, I<sup>2</sup>C Interface, Slave Address, and Ordering Information</i> sections; updated the <i>Simplified Block Diagram, Pin Configurations, Functional Diagrams</i> , Figures 4–Figure 7, Table 1, BBstISet (0x03), BBstCfg1 (0x04), and Table 4; replaced Table 3; added the <i>Inductor Selection</i> and <i>Output Operating Power and Other Optimization</i> sections	1–2, 4–20, 23–25, 28, 32, 34
4.1		Corrected typo	1

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